

## EN29GL064 64 Megabit (8192K x 8-bit / 4096K x 16-bit) Flash Memory Page mode Flash Memory, CMOS 3.0 Volt-only

### FEATURES

- Single power supply operation
- Full voltage range: 2.7 to 3.6 volts read and write operations
- High performance
- Access times as fast as 70 ns
- 8-word/16-byte page read buffer
- 16-word/32-byte write buffer reduces overall programming time for multiple-word updates
- · Secured Silicon Sector region
- 128-word/256-byte sector for permanent, secure identification through an 8-word/16byte random Electronic Serial Number
- Can be programmed and locked at the factory or by the customer
- Flexible Sector Architecture:
- Uniform sector models:
   One hundred and twenty-eight uniform 32Kword/64Kbyte sectors
- Boot sector models: Eight 8-Kbyte boot sectors on Top or Bottom and one hundred twenty-seven 32Kword / 64Kbyte sectors.
- Suspend and Resume commands for Program and Erase operations

- Write operation status bits indicate program and erase operation completion
- Support for CFI (Common Flash Interface)
- Persistent methods of Advanced Sector Protection
- WP#/ACC input
- Accelerates programming time (when  $V_{\text{HH}}$  is applied) for greater throughput during system production
- Protects first or last sector regardless of sector protection settings
- Hardware reset input (RESET#) resets device
- Ready/Busy# output (RY/BY#) detects program or erase cycle completion
- Minimum 100K program/erase endurance cycles.
- Package Options
- 56-pin TSOP
- 64-ball 11mm x 13mm BGA
- Industrial Temperature Range.

### **GENERAL DESCRIPTION**

The EN29GL064 offers a fast page access time of 25 ns with a corresponding random access time as fast as 70 ns. It features a Write Buffer that allows a maximum of 16 words/32 bytes to be programmed in one operation, resulting in faster effective programming time than standard programming algorithms. This makes the device ideal for today's embedded applications that require higher density, better performance and lower power consumption.

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### **CONNECTION DIAGRAMS**



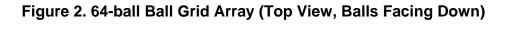


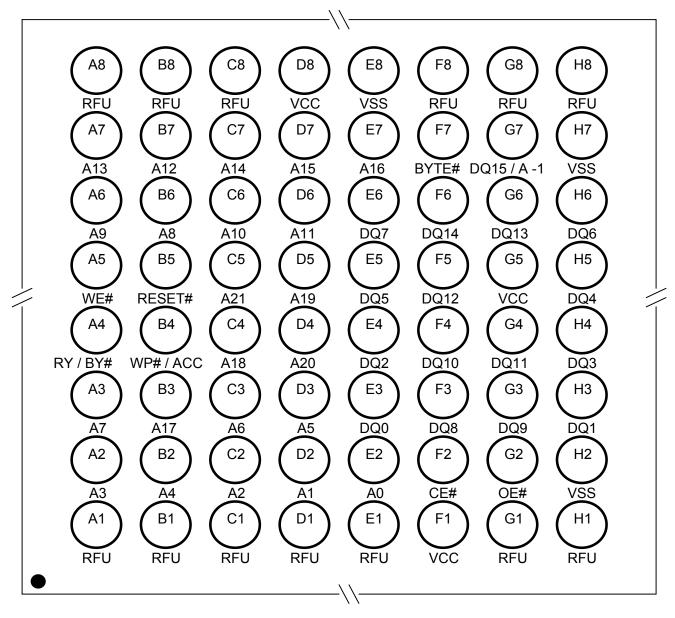
Note: RFU= Reserved for future use Pin 43 and Pin 29 must connect to Vcc at the same time

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Note: RFU= Reserved for future use Pin D8 and Pin F1 must connect to Vcc at the same time

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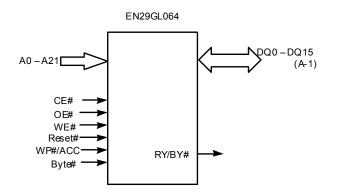
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## TABLE 1. PIN DESCRIPTION

Pin Name	Function			
A21–A0	A21-A0			
DQ0-DQ14	Data input/output.			
DQ15 / A-1	DQ15 (data input/output, word mode), A-1 (LSB address input, byte mode)			
CE#	Chip Enable			
OE#	Output Enable			
RESET#	Hardware Reset Pin			
RY/BY#	Ready/Busy Output			
WE#	Write Enable			
Vcc	Supply Voltage (2.7-3.6V)			
Vss	Ground			
BYTE#	Byte/Word mode selection			
WP#/ACC	Write Protect / Acceleration Pin (WP# has an internal pull-up; when unconnected, WP# is at V <sub>IH</sub> .)			
RFU	Reserved for future use. Not Connected to anything			

### FIGURE 3. LOGIC DIAGRAM



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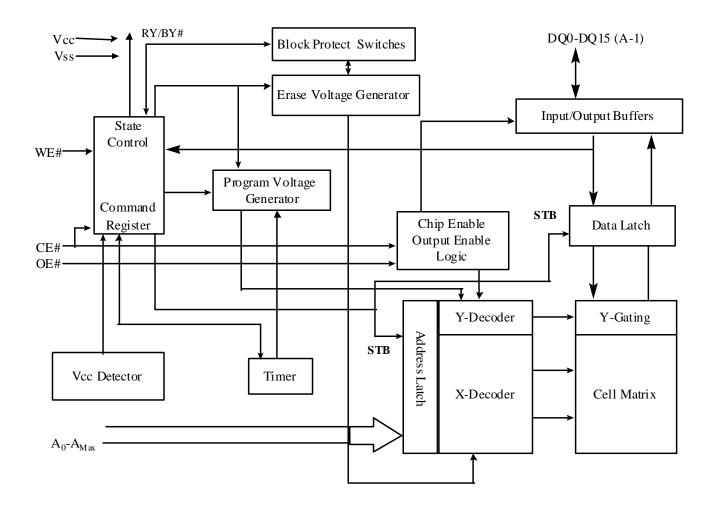
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### Table 2. PRODUCT SELECTOR GUIDE

Product Numb	er	EN29GL064	
Speed Option	Full Voltage Range: Vcc=2.7 – 3.6 V	-70	
Max Access Tin	ne, ns (t <sub>acc</sub> )	70	
Max Page Read	Access, ns(t <sub>pacc</sub> )	25	
Max CE# Acces	ess, ns (t <sub>ce</sub> ) 70		
Max OE# Acces	ss, ns (t <sub>oe</sub> )	25	

### **BLOCK DIAGRAM**



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## **Product Overview**

EN29GL064 is 64 Mb, 3.0-volt-only, page mode Flash devices optimized for today's embedded designs that demand a large storage array and rich functionality. Additional features include:

- Single word programming or a 16-word buffer for an increased programming speed
- Program Suspend/Resume and Erase Suspend/Resume
- Advanced Sector Protection methods for protecting sectors as required
- 128 words/256 bytes of Secured Silicon area for storing customer and factory secured information. The Secured Silicon Sector is One Time Programmable.

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## Table 3A. Uniform Sector / Persistent Protection Sector Group Address Tables (EN29GL064H/L)

PPB Group	Sector	A21–A15	Sector Size (Kbytes/Kwords)	Address Range Byte mode (x8)	Address Range Word mode (x16)
PPB 0	SA0	0000000	64/32	000000h - 00FFFFh	000000h - 007FFFh
PPB 1	SA1	0000001	64/32	010000h - 01FFFFh	008000h - 00FFFFh
PPB 2	SA2	0000010	64/32	020000h - 02FFFFh	010000h - 017FFFh
PPB 3	SA3	0000011	64/32	030000h - 03FFFFh	018000h - 01FFFFh
	SA4	0000100	64/32	040000h - 04FFFFh	020000h - 027FFFh
PPB 4	SA5	0000101	64/32	050000h - 05FFFFh	028000h - 02FFFFh
	SA6	0000110	64/32	060000h - 06FFFFh	030000h - 037FFFh
	SA7	0000111	64/32	070000h - 07FFFFh	038000h - 03FFFFh
	SA8	0001000	64/32	080000h - 08FFFFh	040000h - 047FFFh
PPB 5	SA9	0001001	64/32	090000h - 09FFFFh	048000h - 04FFFFh
РРБЭ	SA10	0001010	64/32	0A0000h - 0AFFFFh	050000h - 057FFFh
	SA11	0001011	64/32	0B0000h - 0BFFFFh	058000h - 05FFFFh
	SA12	0001100	64/32	0C0000h - 0CFFFFh	060000h - 067FFFh
	SA13	0001101	64/32	0D0000h - 0DFFFFh	068000h - 06FFFFh
PPB 6	SA14	0001110	64/32	0E0000h - 0EFFFFh	070000h - 077FFFh
	SA15	0001111	64/32	0F0000h - 0FFFFFh	078000h - 07FFFFh
	SA16	0010000	64/32	100000h - 10FFFFh	080000h - 087FFFh
DDD 7	SA17	0010001	64/32	110000h - 11FFFFh	088000h - 08FFFFh
PPB 7	SA18	0010010	64/32	120000h - 12FFFFh	090000h - 097FFFh
	SA19	0010011	64/32	130000h - 13FFFFh	098000h - 09FFFFh
	SA20	0010100	64/32	140000h - 14FFFFh	0A0000h - 0A7FFFh
	SA21	0010101	64/32	150000h - 15FFFFh	0A8000h - 0AFFFFh
PPB 8	SA22	0010110	64/32	160000h - 16FFFFh	0B0000h - 0B7FFFh
	SA23	0010111	64/32	170000h - 17FFFFh	0B8000h - 0BFFFFh
	SA24	0011000	64/32	180000h - 18FFFFh	0C0000h - 0C7FFFh
	SA25	0011001	64/32	190000h - 19FFFFh	0C8000h - 0CFFFFh
PPB 9	SA26	0011010	64/32	1A0000h - 1AFFFFh	0D0000h - 0D7FFFh
	SA27	0011011	64/32	1B0000h - 1BFFFFh	0D8000h - 0DFFFFh
	SA28	0011100	64/32	1C0000h - 1CFFFFh	0E0000h - 0E7FFFh
	SA29	0011101	64/32	1D0000h - 1DFFFFh	0E8000h - 0EFFFFh
PPB 10	SA30	0011110	64/32	1E0000h - 1EFFFFh	0F0000h - 0F7FFFh
	SA31	0011111	64/32	1F0000h - 1FFFFFh	0F8000h - 0FFFFh
	SA32	0100000	64/32	200000h - 20FFFFh	100000h - 107FFFh
	SA33	0100001	64/32	210000h - 21FFFFh	108000h - 10FFFFh
PPB 11	SA34	0100010	64/32	220000h - 22FFFFh	110000h - 117FFFh
	SA35	0100011	64/32	230000h - 23FFFFh	118000h - 11FFFFh
	SA36	0100100	64/32	240000h - 24FFFFh	120000h - 127FFFh
	SA37	0100101	64/32	250000h - 25FFFFh	128000h - 12FFFFh
PPB 12	SA38	0100110	64/32	260000h - 26FFFFh	130000h - 137FFFh
	SA39	0100111	64/32	270000h - 27FFFFh	138000h - 13FFFFh

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	SA40	0101000	64/32	280000h - 28FFFFh	140000h - 147FFFh
PPB 13	SA41	0101001	64/32	290000h - 29FFFFh	148000h - 14FFFFh
FFDIJ	SA42	0101010	64/32	2A0000h - 2AFFFFh	150000h - 157FFFh
	SA43	0101011	64/32	2B0000h - 2BFFFFh	158000h - 15FFFFh
	SA44	0101100	64/32	2C0000h - 2CFFFFh	160000h - 167FFFh
PPB 14	SA45	0101101	64/32	2D0000h - 2DFFFFh	168000h - 16FFFFh
	SA46	0101110	64/32	2E0000h - 2EFFFFh	170000h - 177FFFh
	SA47	0101111	64/32	2F0000h - 2FFFFFh	178000h - 17FFFFh
	SA48	0110000	64/32	300000h - 30FFFFh	180000h - 187FFFh
PPB 15	SA49	0110001	64/32	310000h - 31FFFFh	188000h - 18FFFFh
PPB 15	SA50	0110010	64/32	320000h - 32FFFFh	190000h - 197FFFh
	SA51	0110011	64/32	330000h - 33FFFFh	198000h - 19FFFFh
	SA52	0110100	64/32	340000h - 34FFFFh	1A0000h - 1A7FFFh
PPB 16	SA53	0110101	64/32	350000h - 35FFFFh	1A8000h - 1AFFFFh
FFD 10	SA54	0110110	64/32	360000h - 36FFFFh	1B0000h - 1B7FFFh
	SA55	0110111	64/32	370000h - 37FFFFh	1B8000h - 1BFFFFh
	SA56	0111000	64/32	380000h - 38FFFFh	1C0000h - 1C7FFFh
PPB 17	SA57	0111001	64/32	390000h - 39FFFFh	1C8000h - 1CFFFFh
FFD I/	SA58	0111010	64/32	3A0000h - 3AFFFFh	1D0000h - 1D7FFFh
	SA59	0111011	64/32	3B0000h - 3BFFFFh	1D8000h - 1DFFFFh
	SA60	0111100	64/32	3C0000h - 3CFFFFh	1E0000h - 1E7FFFh
PPB 18	SA61	0111101	64/32	3D0000h - 3DFFFFh	1E8000h - 1EFFFFh
	SA62	0111110	64/32	3E0000h - 3EFFFFh	1F0000h - 1F7FFFh
	SA63	0111111	64/32	3F0000h - 3FFFFFh	1F8000h - 1FFFFFh
	SA64	1000000	64/32	400000h - 40FFFFh	200000h - 207FFFh
	SA65	1000001	64/32	410000h - 41FFFFh	208000h - 20FFFFh
PPB 19	SA66	1000010	64/32	420000h - 42FFFFh	210000h - 217FFFh
	SA67	1000011	64/32	430000h - 43FFFFh	218000h - 21FFFFh
	SA68	1000100	64/32	440000h - 44FFFFh	220000h - 227FFFh
	SA69	1000101	64/32	450000h - 45FFFFh	228000h - 22FFFFh
PPB 20	SA70	1000110	64/32	460000h - 46FFFFh	230000h - 237FFFh
	SA71	1000111	64/32	470000h - 47FFFFh	238000h - 23FFFFh
	SA72	1001000	64/32	480000h - 48FFFFh	240000h - 247FFFh
PPB 21	SA73	1001001	64/32	490000h - 49FFFFh	248000h - 24FFFFh
	SA74	1001010	64/32	4A0000h - 4AFFFFh	250000h - 257FFFh
	SA75	1001011	64/32	4B0000h - 4BFFFFh	258000h - 25FFFFh
	SA76	1001100	64/32	4C0000h - 4CFFFFh	260000h - 267FFFh
	SA77	1001101	64/32	4D0000h - 4DFFFFh	268000h - 26FFFFh
PPB 22	SA78	1001110	64/32	4E0000h - 4EFFFFh	270000h - 277FFFh
	SA79	1001111	64/32	4F0000h - 4FFFFh	278000h - 27FFFFh
PPB 23	SA80	1010000	64/32	500000h - 50FFFFh	280000h - 287FFFh
	SA81	1010001	64/32	510000h - 51FFFFh	288000h - 28FFFFh
	SA82	1010010	64/32	520000h - 52FFFFh	290000h - 297FFFh

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SA83         1010011         64/32         530000h - 53FFFFh         298000h - 29FFf           PPB 24         SA84         1010100         64/32         540000h - 54FFFFh         2A0000h - 2A7F1           SA85         1010111         64/32         550000h - 55FFFFh         2A8000h - 2A7F1           SA86         1010110         64/32         560000h - 56FFFFh         2B000h - 2B7F1           SA86         1010111         64/32         570000h - 5FFFFh         2B8000h - 2BFF1           SA87         1010111         64/32         580000h - 58FFFFh         2C0000h - 2C7F1           SA88         1011001         64/32         580000h - 58FFFFh         2C8000h - 2CFF1           SA90         1011010         64/32         580000h - 58FFFFh         2C8000h - 2D7F1           SA91         1011011         64/32         560000h - 58FFFFh         2D8000h - 2DFF1           SA93         1011100         64/32         5C0000h - 50FFFFh         2E8000h - 2EFF1           SA94         1011110         64/32         5D0000h - 50FFFFh         2E8000h - 2FF1           SA95         1011110         64/32         5D0000h - 60FFFFh         2E8000h - 307F1           SA95         1011000         64/32         600000h - 60FFFFh         308000h - 307	
PPB 24         SA85         1010101         64/32         550000h - 55FFFFh         2A8000h - 2AFFi           SA86         1010110         64/32         550000h - 56FFFFh         2B000h - 2B7Fi           SA87         1010111         64/32         580000h - 57FFFh         2B8000h - 2B7Fi           SA88         1011000         64/32         580000h - 58FFFFh         2C0000h - 2C7Fi           SA89         101101         64/32         590000h - 58FFFFh         2C8000h - 2C7Fi           SA90         1011010         64/32         50000h - 58FFFFh         2C8000h - 2C7Fi           SA91         101101         64/32         50000h - 58FFFFh         2C8000h - 2C7Fi           SA91         101101         64/32         50000h - 58FFFFh         2D800h - 2D7Fi           SA91         101101         64/32         50000h - 50FFFFh         2D800h - 2E7Fi           SA93         101111         64/32         50000h - 50FFFFh         2E8000h - 2E7Fi           SA93         101111         64/32         50000h - 50FFFFh         2E8000h - 2E7Fi           SA93         101111         64/32         60000h - 60FFFFh         30000h - 30FFi           SA93         101111         64/32         610000h - 61FFFFh         30000h - 30FFi	Fh
PPB 24         SA86         101010         64/32         56000h - 56FFFh         28000h - 287Fi           SA87         1010111         64/32         57000h - 57FFFh         28000h - 28FFi           SA88         101100         64/32         58000h - 58FFFh         2C000h - 2C7Fi           SA88         101100         64/32         59000h - 59FFFh         2C8000h - 2C7Fi           SA90         101101         64/32         50000h - 58FFFh         2C8000h - 2C7Fi           SA91         101101         64/32         50000h - 58FFFh         2D8000h - 2D7Fi           SA91         101101         64/32         5C0000h - 56FFFh         2D8000h - 2E7Fi           SA92         101110         64/32         5C0000h - 50FFFh         2E8000h - 2E7Fi           SA93         101111         64/32         5D000h - 50FFFh         2E8000h - 2FFi           SA93         101111         64/32         5D000h - 50FFFh         2E8000h - 2FFi           SA95         101111         64/32         60000h - 60FFFh         30000h - 307Fi           SA95         101111         64/32         61000h - 61FFFh         30800h - 30FFi           PB 27         SA96         110001         64/32         62000h - 62FFFh         310000h - 317Fi	Fh
SA86         1010110         64/32         560000h - 56FFFFh         2B0000h - 2B7Ff           SA87         1010111         64/32         570000h - 57FFFFh         2B8000h - 2BFFf           PPB 25         SA88         1011000         64/32         580000h - 58FFFFh         2C0000h - 2C7Ff           SA89         1011011         64/32         590000h - 59FFFFh         2C8000h - 2CFF           SA90         1011010         64/32         580000h - 58FFFFh         2D000h - 2D7Ff           SA91         1011011         64/32         5B0000h - 58FFFFh         2D000h - 2D7Ff           SA91         1011010         64/32         5C0000h - 50FFFFh         2E0000h - 2D7Ff           SA92         1011101         64/32         5C0000h - 50FFFFh         2E0000h - 2D7Ff           SA93         1011101         64/32         5D0000h - 50FFFh         2E8000h - 2EFFf           SA93         1011111         64/32         5D0000h - 50FFFFh         2E8000h - 2EFFf           SA95         1011111         64/32         610000h - 61FFFFh         300000h - 30Fff           SA95         1011111         64/32         610000h - 61FFFFh         308000h - 30Fff           SA98         1100010         64/32         610000h - 61FFFFh         308000h - 30Ff	
PPB 25         SA88         1011000         64/32         58000h - 58FFFh         2C000h - 2C7Fi           SA89         1011001         64/32         590000h - 59FFFh         2C8000h - 2CFF           SA90         1011010         64/32         5A000h - 5AFFFFh         2D8000h - 2D7FI           SA91         1011011         64/32         5C000h - 5AFFFFh         2D8000h - 2E7FI           SA91         101101         64/32         5C000h - 5CFFFFh         2E0000h - 2E7FI           SA93         1011101         64/32         5C000h - 5CFFFFh         2E000h - 2E7FI           SA93         1011101         64/32         5C000h - 5CFFFFh         2E000h - 2E7FI           SA93         101111         64/32         5C000h - 5EFFFFh         2E000h - 2E7FI           SA95         101111         64/32         5E000h - 5EFFFFh         2E800h - 2EFFI           SA95         101111         64/32         60000h - 60FFFFh         30000h - 307FF           SA96         1100001         64/32         610000h - 61FFFFh         30800h - 30FF           SA97         1100011         64/32         63000h - 63FFFFh         31800h - 31FF           SA99         1100101         64/32         63000h - 63FFFFh         318000h - 31FF	Fh
PPB 25         SA89         1011001         64/32         59000h - 59FFFh         2C8000h - 2CFF           SA90         1011010         64/32         5A0000h - 5AFFFFh         2D0000h - 2D7FI           SA91         1011011         64/32         5B0000h - 5BFFFFh         2D8000h - 2D7FI           PPB 26         SA92         1011100         64/32         5C0000h - 5CFFFFh         2E0000h - 2E7FI           SA93         1011101         64/32         5D0000h - 5DFFFFh         2E8000h - 2E7FI           SA93         1011110         64/32         5D000h - 5DFFFFh         2E8000h - 2E7FI           SA94         1011111         64/32         5E0000h - 5EFFFFh         2E8000h - 2F7FI           SA95         1011111         64/32         5E0000h - 5EFFFFh         2E8000h - 2F7FI           SA95         1011111         64/32         60000h - 60FFFFh         30000h - 307FI           SA96         1100000         64/32         60000h - 61FFFFh         30800h - 30FFI           SA98         1100011         64/32         63000h - 63FFFFh         31800h - 31FFI           SA99         1100011         64/32         63000h - 63FFFFh         318000h - 32FFI           SA100         1100100         64/32         650000h - 65FFFFh	Fh
PPB 25         SA90         1011010         64/32         5A0000h - 5AFFFFh         2D0000h - 2D7Fi           SA91         1011011         64/32         5B0000h - 5BFFFh         2D8000h - 2DFFi           PPB 26         SA92         1011100         64/32         5C0000h - 5CFFFFh         2E0000h - 2E7Fi           SA93         1011101         64/32         5C0000h - 5DFFFFh         2E8000h - 2E7Fi           SA93         1011110         64/32         5D0000h - 5DFFFFh         2E8000h - 2E7Fi           SA94         1011110         64/32         5E0000h - 5FFFFh         2E8000h - 2E7Fi           SA95         1011111         64/32         5E0000h - 5FFFFh         2E8000h - 2F7Fi           SA95         1011111         64/32         5E0000h - 5FFFFh         2E8000h - 2F7Fi           SA95         1011111         64/32         5E0000h - 6FFFFh         30000h - 307Ff           SA95         101001         64/32         610000h - 6FFFFh         30800h - 307Ff           SA98         1100010         64/32         620000h - 62FFFFh         310000h - 317Ff           SA99         1100010         64/32         630000h - 62FFFFh         32000h - 32Fff           PB 28         SA101         1100101         64/32         650000h	Fh
SA90         1011010         64/32         5A000h - 5AFFFFh         2D000h - 2D7Fh           SA91         1011011         64/32         5B000h - 5BFFFFh         2D800h - 2DFFh           PPB 26         SA92         1011100         64/32         5C0000h - 5CFFFFh         2E0000h - 2E7Fh           SA93         1011101         64/32         5D000h - 5DFFFFh         2E000h - 2E7Fh           SA94         1011110         64/32         5E000h - 5EFFFFh         2E800h - 2EFFh           SA95         1011111         64/32         5F000h - 5FFFFh         2E800h - 2FFh           SA95         1011111         64/32         5F000h - 5FFFFh         2F800h - 2FFh           SA95         1011111         64/32         5F000h - 5FFFFh         2F800h - 2FFh           SA95         1011111         64/32         5F000h - 6FFFFh         30000h - 307Fh           SA96         1100010         64/32         610000h - 61FFFh         30800h - 30FFh           SA99         1100011         64/32         620000h - 62FFFFh         31800h - 31FFh           SA99         1100110         64/32         640000h - 64FFFh         32000h - 32FFh           SA101         1100101         64/32         650000h - 6FFFFh         328000h - 33FFh <tr< td=""><td>Fh</td></tr<>	Fh
PPB 26         SA92         1011100         64/32         5C0000h - 5CFFFFh         2E0000h - 2E7FI           SA93         1011101         64/32         5D0000h - 5DFFFh         2E8000h - 2EFFI           SA94         1011110         64/32         5E0000h - 5EFFFh         2E8000h - 2EFFI           SA94         1011110         64/32         5E0000h - 5EFFFh         2F8000h - 2FFI           SA95         1011111         64/32         5F0000h - 5FFFFh         2F8000h - 2FFI           SA95         1011111         64/32         610000h - 6FFFFh         2F8000h - 2FFI           SA95         1010010         64/32         610000h - 6FFFFh         30000h - 307FF           SA98         1100010         64/32         620000h - 62FFFFh         31800h - 31FFF           SA99         1100011         64/32         630000h - 63FFFFh         31800h - 31FFF           SA100         1100100         64/32         630000h - 64FFFFh         328000h - 32FFF           SA101         110010         64/32         630000h - 64FFFFh         328000h - 32FFF           SA101         110010         64/32         640000h - 64FFFFh         328000h - 32FFF           SA102         1100101         64/32         650000h - 6FFFFh         338000h - 33FFF	Fh
PPB 26         SA93         1011101         64/32         5D0000h - 5DFFFFh         2E8000h - 2EFFI           SA94         1011110         64/32         5E0000h - 5EFFFFh         2F000h - 2F7FI           SA95         1011111         64/32         5F0000h - 5FFFFh         2F8000h - 2F7FI           SA95         1011111         64/32         5F0000h - 5FFFFh         2F8000h - 2F7FI           SA95         1011111         64/32         600000h - 60FFFFh         30000h - 307FF           SA97         110000         64/32         610000h - 61FFFFh         30800h - 307FF           SA98         1100010         64/32         620000h - 62FFFFh         318000h - 317FF           SA98         1100010         64/32         630000h - 63FFFFh         318000h - 317FF           SA100         1100100         64/32         640000h - 64FFFFh         32000h - 327FF           SA101         1100101         64/32         650000h - 65FFFFh         328000h - 327FF           SA101         1100101         64/32         650000h - 65FFFFh         328000h - 327FF           SA102         1100110         64/32         660000h - 66FFFFh         338000h - 337FF           SA103         1100110         64/32         670000h - 67FFFFh         348000h - 34	Fh
PPB 26         SA94         1011110         64/32         5E0000h - 5EFFFFh         2F0000h - 2F7Ff           SA95         1011111         64/32         5F0000h - 5FFFFh         2F8000h - 2F7Ff           PPB 27         SA96         1100000         64/32         600000h - 60FFFFh         30000h - 307Ff           SA97         1100011         64/32         610000h - 61FFFFh         308000h - 307Ff           SA98         1100010         64/32         620000h - 62FFFFh         310000h - 317Ff           SA98         1100011         64/32         630000h - 63FFFFh         318000h - 317Ff           SA99         1100010         64/32         630000h - 63FFFFh         328000h - 327Ff           SA100         1100100         64/32         640000h - 64FFFFh         328000h - 327Ff           SA101         1100101         64/32         650000h - 65FFFFh         328000h - 327Ff           SA102         1100110         64/32         650000h - 65FFFFh         328000h - 337Ff           SA103         1100110         64/32         660000h - 65FFFFh         338000h - 337Ff           SA103         1100101         64/32         680000h - 68FFFFh         340000h - 347Ff           SA105         1101001         64/32         680000h - 68FFFFh	Fh
SA94         1011110         64/32         5E000h - 5EFFFh         2F000h - 2F7F           SA95         1011111         64/32         5F000h - 5FFFFh         2F800h - 2FFF           PPB 27         SA96         110000         64/32         60000h - 60FFFFh         30000h - 307FF           SA97         1100001         64/32         610000h - 61FFFFh         30800h - 30FFF           SA98         1100010         64/32         620000h - 62FFFFh         310000h - 317FF           SA99         1100011         64/32         630000h - 63FFFFh         318000h - 317FF           SA99         1100100         64/32         630000h - 63FFFFh         318000h - 317FF           SA100         1100100         64/32         640000h - 63FFFFh         328000h - 327FF           SA101         1100101         64/32         650000h - 65FFFFh         328000h - 327FF           SA102         1100101         64/32         650000h - 65FFFFh         328000h - 327FF           SA102         1100110         64/32         650000h - 65FFFFh         338000h - 337FF           SA103         1100111         64/32         660000h - 67FFFFh         338000h - 347FF           SA105         1101001         64/32         680000h - 68FFFFh         348000h - 347FF<	Fh
PPB 27         SA96         110000         64/32         60000h - 60FFFFh         30000h - 307FF           SA97         110001         64/32         610000h - 61FFFh         30800h - 30FFF           SA97         110001         64/32         610000h - 61FFFh         30800h - 30FFF           SA98         1100010         64/32         620000h - 62FFFFh         310000h - 317FF           SA99         110011         64/32         630000h - 63FFFFh         318000h - 317FF           SA100         1100100         64/32         640000h - 63FFFFh         320000h - 327FF           SA101         110010         64/32         650000h - 63FFFFh         328000h - 327FF           SA101         110010         64/32         660000h - 66FFFFh         328000h - 32FFF           SA102         1100110         64/32         660000h - 66FFFFh         338000h - 33FFF           SA103         1100110         64/32         680000h - 68FFFFh         340000h - 347FF           SA103         110100         64/32         680000h - 68FFFFh         348000h - 34FFF           SA105         110100         64/32         680000h - 68FFFFh         358000h - 35FFF           SA106         110101         64/32         620000h - 68FFFFh         358000h - 35FFF </td <td>Fh</td>	Fh
PPB 27         SA97         1100001         64/32         61000h - 61FFFFh         30800h - 30FFF           SA98         1100010         64/32         62000h - 62FFFFh         31000h - 317FF           SA99         1100011         64/32         63000h - 63FFFFh         31800h - 31FFF           SA99         1100110         64/32         63000h - 63FFFFh         31800h - 31FFF           SA100         1100100         64/32         640000h - 64FFFFh         32000h - 327FF           SA101         1100101         64/32         650000h - 65FFFFh         328000h - 327FF           SA101         1100110         64/32         660000h - 66FFFFh         328000h - 327FF           SA102         1100110         64/32         660000h - 65FFFFh         328000h - 327FF           SA103         1100111         64/32         660000h - 66FFFFh         338000h - 337FF           SA103         1100110         64/32         680000h - 68FFFFh         340000h - 347FF           PB 29         SA105         1101001         64/32         690000h - 69FFFFh         348000h - 347FF           SA104         1101001         64/32         680000h - 68FFFFh         35000h - 357FF           SA106         1101010         64/32         6B0000h - 60FFFFh	Fh
PPB 27         SA98         1100010         64/32         620000h - 62FFFFh         310000h - 317FF           SA99         1100011         64/32         630000h - 63FFFFh         318000h - 31FFF           SA99         1100100         64/32         640000h - 63FFFFh         320000h - 32FFF           PPB 28         SA101         1100101         64/32         650000h - 65FFFFh         328000h - 32FFF           SA102         1100110         64/32         650000h - 65FFFFh         328000h - 32FFF           SA102         1100110         64/32         660000h - 66FFFFh         338000h - 33FFF           SA103         1100111         64/32         670000h - 67FFFFh         338000h - 33FFF           SA103         1100101         64/32         670000h - 67FFFFh         340000h - 347FF           SA104         1101000         64/32         680000h - 68FFFFh         340000h - 347FF           SA105         1101010         64/32         690000h - 68FFFFh         348000h - 347FF           SA106         1101010         64/32         680000h - 68FFFFh         350000h - 357FF           SA107         1101010         64/32         6B0000h - 68FFFFh         360000h - 367FF           SA108         1101100         64/32         6C0000h - 6	Fh
SA98         1100010         64/32         620000h - 62FFFFh         31000h - 317FF           SA99         1100011         64/32         630000h - 63FFFFh         318000h - 317FF           SA100         1100100         64/32         640000h - 63FFFFh         320000h - 327FF           SA101         1100101         64/32         650000h - 64FFFFh         328000h - 327FF           SA101         1100101         64/32         650000h - 65FFFFh         328000h - 327FF           SA102         1100110         64/32         650000h - 65FFFFh         328000h - 327FF           SA103         1100110         64/32         650000h - 65FFFFh         328000h - 327FF           SA103         1100110         64/32         660000h - 66FFFFh         338000h - 337FF           SA103         1101010         64/32         670000h - 67FFFFh         338000h - 347FF           SA105         1101001         64/32         680000h - 68FFFFh         340000h - 347FF           SA106         1101010         64/32         680000h - 68FFFFh         358000h - 357FF           SA106         1101010         64/32         6B0000h - 68FFFFh         358000h - 357FF           SA107         1101011         64/32         6D0000h - 60FFFFh         368000h - 367FF	Fh
PPB 28         SA100         1100100         64/32         640000h - 64FFFFh         32000h - 327FF           SA101         1100101         64/32         650000h - 65FFFFh         328000h - 32FFF           SA102         1100110         64/32         660000h - 65FFFFh         328000h - 32FFF           SA102         1100110         64/32         660000h - 65FFFFh         338000h - 337FF           SA103         1100111         64/32         670000h - 67FFFFh         338000h - 337FF           SA103         1100111         64/32         670000h - 67FFFFh         338000h - 347FF           SA104         1101000         64/32         680000h - 68FFFFh         348000h - 347FF           SA105         1101001         64/32         690000h - 69FFFFh         348000h - 347FF           SA106         1101010         64/32         690000h - 69FFFFh         358000h - 357FF           SA106         1101010         64/32         6B0000h - 6BFFFFh         358000h - 357FF           SA107         1101011         64/32         6B0000h - 6DFFFFh         368000h - 367FF           SA109         1101101         64/32         6D0000h - 6DFFFFh         368000h - 367FF           SA110         1101110         64/32         6E00000h - 6DFFFFh         <	Fh
PPB 28         SA101         1100101         64/32         650000h - 65FFFFh         328000h - 32FFF           SA102         1100110         64/32         660000h - 66FFFFh         330000h - 337FF           SA103         1100111         64/32         670000h - 67FFFFh         338000h - 33FFF           SA103         1100111         64/32         670000h - 67FFFFh         338000h - 33FFF           SA104         1101000         64/32         680000h - 68FFFFh         340000h - 347FF           SA105         1101001         64/32         690000h - 69FFFFh         348000h - 34FFF           SA105         1101001         64/32         690000h - 69FFFFh         348000h - 34FFF           SA106         1101010         64/32         690000h - 69FFFFh         358000h - 35FFF           SA107         1101011         64/32         6B0000h - 6BFFFFh         358000h - 36FFF           SA107         1101011         64/32         6C0000h - 6DFFFFh         368000h - 36FFF           SA109         1101101         64/32         6D0000h - 6DFFFFh         378000h - 37FFF           SA110         1101110         64/32         6E0000h - 6EFFFFh         378000h - 37FFF           SA111         1101111         64/32         6F00000h - 6FFFFFh	Fh
PPB 28         SA102         1100110         64/32         660000h - 66FFFFh         330000h - 337FF           SA103         1100111         64/32         670000h - 67FFFFh         338000h - 33FFF           SA103         1100111         64/32         670000h - 67FFFFh         338000h - 33FFF           SA104         1101000         64/32         680000h - 68FFFFh         340000h - 347FF           SA105         1101001         64/32         690000h - 68FFFFh         348000h - 34FFF           SA106         1101010         64/32         690000h - 68FFFFh         358000h - 35FFF           SA106         1101011         64/32         680000h - 68FFFFh         358000h - 35FFF           SA107         1101011         64/32         6B0000h - 68FFFFh         358000h - 35FFF           SA107         1101011         64/32         6B0000h - 60FFFFh         368000h - 36FFF           SA108         1101100         64/32         6C0000h - 60FFFFh         368000h - 36FFF           SA109         1101101         64/32         6D0000h - 60FFFFh         378000h - 37FFF           SA110         1101111         64/32         6E0000h - 6FFFFFh         378000h - 37FFF           SA111         1101111         64/32         6F00000h - 6FFFFFh	Fh
SA102         1100110         64/32         660000h - 66FFFh         330000h - 337FF           SA103         1100111         64/32         670000h - 67FFFh         338000h - 337FF           SA103         1100111         64/32         670000h - 67FFFFh         338000h - 337FF           PPB 29         SA104         1101000         64/32         680000h - 68FFFFh         340000h - 347FF           SA105         1101001         64/32         690000h - 69FFFFh         348000h - 34FFF           SA106         1101010         64/32         6A0000h - 68FFFFh         350000h - 357FF           SA107         1101011         64/32         6B0000h - 68FFFFh         358000h - 357FF           SA107         1101011         64/32         6B0000h - 68FFFFh         358000h - 357FF           SA108         1101100         64/32         6B0000h - 68FFFFh         368000h - 367FF           SA109         1101101         64/32         6C0000h - 6CFFFFh         368000h - 367FF           SA110         1101110         64/32         6E0000h - 6EFFFFh         378000h - 377FF           SA111         1101111         64/32         6F0000h - 6FFFFFh         378000h - 37FFF	Fh
PPB 29         SA104         1101000         64/32         680000h - 68FFFFh         340000h - 347FF           SA105         1101001         64/32         690000h - 69FFFFh         348000h - 34FFF           SA106         1101010         64/32         690000h - 69FFFFh         348000h - 34FFF           SA106         1101010         64/32         6A0000h - 6AFFFFh         350000h - 35FFF           SA107         1101011         64/32         6B0000h - 6BFFFFh         358000h - 35FFF           SA108         1101100         64/32         6C0000h - 6DFFFFh         368000h - 36FFF           SA109         1101101         64/32         6D0000h - 6DFFFFh         368000h - 36FFF           SA110         1101110         64/32         6D0000h - 6DFFFFh         378000h - 37FFF           SA111         1101111         64/32         6F0000h - 6FFFFFh         378000h - 37FFF	Fh
PPB 29         SA105         1101001         64/32         690000h - 69FFFFh         348000h - 34FFF           SA106         1101010         64/32         6A0000h - 69FFFFh         350000h - 357FF           SA107         1101011         64/32         6A0000h - 6AFFFFh         358000h - 357FF           SA107         1101011         64/32         6B0000h - 6BFFFFh         358000h - 35FFF           SA108         1101100         64/32         6C0000h - 6CFFFFh         368000h - 367FF           SA109         1101101         64/32         6D0000h - 6DFFFFh         368000h - 367FF           SA110         1101110         64/32         6D0000h - 6DFFFFh         378000h - 377FF           SA111         1101111         64/32         6F0000h - 6FFFFFh         378000h - 37FFF	Fh
PPB 29         SA106         1101010         64/32         6A0000h - 6AFFFFh         350000h - 357FF           SA107         1101011         64/32         6B0000h - 6BFFFFh         358000h - 35FFF           SA107         1101011         64/32         6B0000h - 6BFFFFh         358000h - 35FFF           SA108         1101100         64/32         6C0000h - 6CFFFFh         360000h - 367FF           SA109         1101101         64/32         6D0000h - 6DFFFFh         368000h - 36FFF           SA110         1101110         64/32         6E0000h - 6EFFFFh         370000h - 37FFF           SA111         1101111         64/32         6F0000h - 6FFFFFh         378000h - 37FFF	Fh
SA106         1101010         64/32         6A0000h - 6AFFFFh         350000h - 357FF           SA107         1101011         64/32         6B0000h - 6BFFFFh         358000h - 357FF           SA108         1101100         64/32         6C0000h - 6BFFFFh         360000h - 367FF           SA109         1101101         64/32         6C0000h - 6DFFFFh         368000h - 367FF           SA109         1101101         64/32         6D0000h - 6DFFFFh         368000h - 367FF           SA110         1101110         64/32         6E0000h - 6EFFFFh         378000h - 377FF           SA111         1101111         64/32         6F0000h - 6FFFFFh         378000h - 37FFF	Fh
SA108         1101100         64/32         6C0000h - 6CFFFFh         360000h - 367FF           SA109         1101101         64/32         6D0000h - 6DFFFFh         368000h - 367FF           SA109         1101101         64/32         6D0000h - 6DFFFFh         368000h - 36FFF           SA110         1101110         64/32         6E0000h - 6EFFFFh         370000h - 37FFF           SA111         1101111         64/32         6F0000h - 6FFFFFh         378000h - 37FFF	Fh
SA109         1101101         64/32         6D0000h - 6DFFFFh         368000h - 36FFF           SA110         1101110         64/32         6E0000h - 6EFFFFh         370000h - 377FF           SA111         1101111         64/32         6F0000h - 6FFFFFh         378000h - 37FFF	Fh
PPB 30         SA110         1101110         64/32         6E0000h - 6EFFFFh         370000h - 377FF           SA111         1101111         64/32         6F0000h - 6FFFFFh         378000h - 37FFF	Fh
SA110         1101110         64/32         6E0000h - 6EFFFFh         370000h - 377FF           SA111         1101111         64/32         6F0000h - 6FFFFFh         378000h - 37FFF	Fh
	Fh
	Fh
SA112 1110000 64/32 700000h - 70FFFh 380000h - 387FF	Fh
PPB 31 SA113 1110001 64/32 710000h - 71FFFFh 388000h - 38FFF	Fh
SA114 1110010 64/32 720000h - 72FFFh 390000h - 397Ff	Fh
SA115 1110011 64/32 730000h - 73FFFFh 398000h - 39FFF	Fh
SA116 1110100 64/32 740000h - 74FFFh 3A0000h - 3A7FI	Fh
SA117 1110101 64/32 750000h - 75FFFh 3A8000h - 3AFFI	Fh
PPB 32         SA118         1110110         64/32         760000h - 76FFFFh         3B0000h - 3B7FF	Fh
SA119 1110111 64/32 770000h - 77FFFh 3B8000h - 3BFFI	Fh
SA120 1111000 64/32 780000h - 78FFFFh 3C0000h - 3C7Fl	Fh
SA121 1111001 64/32 790000h - 79FFFFh 3C8000h - 3CFF	Fh
PPB 33         SA122         1111010         64/32         7A0000h - 7AFFFFh         3D0000h - 3D7Fl	Fh
SA123 1111011 64/32 7B0000h - 7BFFFFh 3D8000h - 3DFF	-Fh
PPB 34 SA124 1111100 64/32 7C0000h - 7CFFFFh 3E0000h - 3E7FI	Fh
PPB 35 SA125 1111101 64/32 7D0000h - 7DFFFFh 3E8000h - 3EFFI	Fh

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PPB 36	SA126	1111110	64/32	7E0000h - 7EFFFh	3F0000h - 3F7FFFh
PPB 37	SA127	1111111	64/32	7F0000h - 7FFFFFh	3F8000h - 3FFFFFh

## Table 3B. Top Boot Sector / Persistent Protection Sector Group Address Tables (EN29GL064T)

PPB Group	Sector	A21 – A12	Sector Size (Kbytes / Kwords)	Address Range (h) Byte mode (x8)	Address Range (h) Word Mode (x16)
	SA0	000000xxx	64/32	000000-00FFFF	000000-007FFF
PPB 0	SA1	0000001xxx	64/32	010000–01FFFF	008000-00FFFF
	SA2	0000010xxx	64/32	020000-02FFFF	010000–017FFF
	SA3	0000011xxx	64/32	030000–03FFFF	018000-01FFFF
	SA4	0000100xxx	64/32	040000-04FFFF	020000-027FFF
PPB 1	SA5	0000101xxx	64/32	050000-05FFFF	028000-02FFFF
FFDI	SA6	0000110xxx	64/32	060000-06FFFF	030000-037FFF
	SA7	0000111xxx	64/32	070000–07FFFF	038000-03FFFF
	SA8	0001000xxx	64/32	080000–08FFFF	040000–047FFF
PPB 2	SA9	0001001xxx	64/32	090000-09FFFF	048000-04FFFF
	SA10	0001010xxx	64/32	0A0000-0AFFFF	050000–057FFF
	SA11	0001011xxx	64/32	0B0000-0BFFFF	058000-05FFFF
	SA12	0001100xxx	64/32	0C0000-0CFFFF	060000-067FFF
PPB 3	SA13	0001101xxx	64/32	0D0000-0DFFFF	068000-06FFFF
PPBS	SA14	0001110xxx	64/32	0E0000-0EFFFF	070000–077FFF
	SA15	0001111xxx	64/32	0F0000-0FFFFF	078000–07FFFF
	SA16	0010000xxx	64/32	100000-10FFFF	080000–087FFF
PPB 4	SA17	0010001xxx	64/32	110000–11FFFF	088000-08FFFF
FFD 4	SA18	0010010xxx	64/32	120000–12FFFF	090000–097FFF
	SA19	0010011xxx	64/32	130000–13FFFF	098000-09FFFF
PPB 5	SA20	0010100xxx	64/32	140000–14FFFF	0A0000-0A7FFF
	SA21	0010101xxx	64/32	150000–15FFFF	0A8000-0AFFFF
	SA22	0010110xxx	64/32	160000–16FFFF	0B0000-0B7FFF
	SA23	0010111xxx	64/32	170000–17FFFF	0B8000-0BFFFF
	SA24	0011000xxx	64/32	180000–18FFFF	0C0000-0C7FFF
	SA25	0011001xxx	64/32	190000–19FFFF	0C8000-0CFFFF
PPB 6	SA26	0011010xxx	64/32	1A0000–1AFFFF	0D0000-0D7FFF
	SA27	0011011xxx	64/32	1B0000–1BFFFF	0D8000-0DFFFF
	SA28	0011100xxx	64/32	1C0000-1CFFFF	0E0000-0E7FFF
PPB 7	SA29	0011101xxx	64/32	1D0000–1DFFFF	0E8000-0EFFFF
FFD /	SA30	0011110xxx	64/32	1E0000–1EFFFF	0F0000-0F7FFF
	SA31	0011111xxx	64/32	1F0000–1FFFFF	0F8000-0FFFFF
	SA32	0100000xxx	64/32	200000–20FFFF	100000–107FFF
	SA33	0100001xxx	64/32	210000–21FFFF	108000–10FFFF
PPB 8	SA34	0100010xxx	64/32	220000-22FFFF	110000–117FFF
	SA35	0100011xxx	64/32	230000–23FFFF	118000–11FFFF
PPB 9	SA36	0100100xxx	64/32	240000-24FFFF	120000–127FFF

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		1			
	SA37	0100101xxx	64/32	250000–25FFFF	128000–12FFFF
	SA38	0100110xxx	64/32	260000–26FFFF	130000–137FFF
	SA39	0100111xxx	64/32	270000–27FFFF	138000–13FFFF
	SA40	0101000xxx	64/32	280000–28FFFF	140000–147FFF
PPB 10	SA41	0101001xxx	64/32	290000–29FFFF	148000–14FFFF
FEDIO	SA42	0101010xxx	64/32	2A0000–2AFFFF	150000–157FFF
	SA43	0101011xxx	64/32	2B0000–2BFFFF	158000–15FFFF
	SA44	0101100xxx	64/32	2C0000-2CFFFF	160000–167FFF
PPB 11	SA45	0101101xxx	64/32	2D0000-2DFFFF	168000–16FFFF
РРВП	SA46	0101110xxx	64/32	2E0000-2EFFFF	170000–177FFF
	SA47	0101111xxx	64/32	2F0000–2FFFFF	178000–17FFFF
	SA48	0110000xxx	64/32	300000-30FFFF	180000–187FFF
	SA49	0110001xxx	64/32	310000–31FFFF	188000–18FFFF
PPB 12	SA50	0110010xxx	64/32	320000–32FFFF	190000–197FFF
	SA51	0110011xxx	64/32	330000–33FFFF	198000–19FFFF
	SA52	0110100xxx	64/32	340000–34FFFF	1A0000–1A7FFF
	SA53	0110101xxx	64/32	350000–35FFFF	1A8000–1AFFFF
PPB 13	SA54	0110110xxx	64/32	360000–36FFFF	1B0000–1B7FFF
	SA55	0110111xxx	64/32	370000–37FFFF	1B8000–1BFFFF
	SA56	0111000xxx	64/32	380000–38FFFF	1C0000-1C7FFF
	SA57	0111001xxx	64/32	390000–39FFFF	1C8000-1CFFFF
PPB 14	SA58	0111010xxx	64/32	3A0000–3AFFFF	1D0000-1D7FFF
	SA59	0111011xxx	64/32	3B0000–3BFFFF	1D8000–1DFFFF
	SA60	0111100xxx	64/32	3C0000-3CFFFF	1E0000-1E7FFF
	SA61	0111101xxx	64/32	3D0000-3DFFFF	1E8000–1EFFFF
PPB 15 -	SA62	0111110xxx	64/32	3E0000–3EFFFF	1F0000–1F7FFF
-	SA63	0111111xxx	64/32	3F0000–3FFFFF	1F8000–1FFFFF
	SA64	1000000xxx	64/32	400000-40FFFF	200000–207FFF
PPB 16	SA65	1000001xxx	64/32	410000–41FFFF	208000-20FFFF
	SA66	1000010xxx	64/32	420000-42FFFF	210000–217FFF
	SA67	1000011xxx	64/32	430000–43FFFF	218000–21FFFF
	SA68	1000100xxx	64/32	440000–44FFFF	220000–227FFF
	SA69	1000101xxx	64/32	450000–45FFFF	228000-22FFFF
PPB 17	SA70	1000110xxx	64/32	460000-46FFFF	230000–237FFF
	SA71	1000111xxx	64/32	470000–47FFFF	238000–23FFFF
	SA72	1001000xxx	64/32	480000–48FFFF	240000–247FFF
	SA73	1001001xxx	64/32	490000–49FFFF	248000–24FFFF
PPB 18	SA74	1001010xxx	64/32	4A0000–4AFFFF	250000–257FFF
	SA75	1001011xxx	64/32	4B0000–4BFFFF	258000–25FFFF
	SA76	1001100xxx	64/32	4C0000-4CFFFF	260000–267FFF
	SA77	1001101xxx	64/32	4D0000-4DFFFF	268000–26FFFF
PPB 19	SA78	1001110xxx	64/32	4E0000-4EFFFF	270000–277FFF
-	SA79	1001111xxx	64/32	4F0000–4FFFFF	278000–27FFFF

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SA80           SA81           SA81           SA82           SA83           SA84           SA85           SA86           SA87           SA88           SA90           SA91           SA93           SA94           SA95           SA94           SA95           SA96           SA97           SA98           SA98           SA99           SA100           SA101           SA102           SA103           SA104           SA105           SA106           SA107           SA106           SA107           SA106      SA107     <	1010000xxx 1010001xxx 1010010xxx 1010010xxx 1010100xxx 1010100xxx 1010110xxx 1010111xxx 1010111xxx 1011000xxx 1011010xxx 1011101xxx 1011101xxx 1011110xxx 1011100xxx 1011100xxx 101110xxx 101110xxx 101110xxx 101100xxx 101100xxx 101100xxx 101100xxx 101100xxx 101100xxx 101100xxx 101100xxx 101100xxx 101100xxx 101100xxx 101100xxx 101100xxx 101100xxx	64/32         64/32	500000-50FFFF           510000-51FFFF           520000-52FFFF           530000-53FFFF           540000-54FFFF           550000-55FFFF           560000-56FFFF           570000-57FFFF           580000-58FFFF           590000-59FFFF           580000-58FFFF           580000-58FFFF           590000-59FFFF           580000-58FFFF           550000-50FFFF           560000-50FFFF           560000-50FFFF           560000-50FFFF	280000–287FFF 288000–287FFF 290000–297FFF 298000–297FFF 2A0000–2A7FFF 2A0000–2A7FFF 2B0000–2B7FFF 2B0000–2B7FFF 2C0000–2C7FFF 2C0000–2C7FFF 2D0000–2D7FFF 2E0000–2D7FFF 2E8000–2E7FFF 2F0000–2F7FFF
PPB 20         SA82           SA83         SA83           SA84         SA84           SA85         SA86           SA86         SA87           SA88         SA87           SA88         SA89           PPB 22         SA90           SA91         SA91           SA92         SA93           SA93         SA94           SA95         SA93           SA94         SA95           SA95         SA93           SA94         SA95           SA95         SA96           SA97         SA98           SA98         SA99           SA100         SA101           SA102         SA102           SA103         SA104           SA105         SA106           SA106         SA107	1010010xxx 1010011xxx 1010100xxx 1010100xxx 1010110xxx 1010110xxx 1011000xxx 1011001xxx 1011010xxx 1011010xxx 1011101xxx 1011110xxx 1011110xxx 1011110xxx 10111110xxx 10111110xxx 10111110xxx 10111110xxx 10111110xxx 10111110xxx 10111110xxx 10111110xxx 10111110xxx 10111110xxx 10111110xxx 10111110xxx 1011110xxx 1011110xxx 1011110xxx 1011100xxx 1011100xxx	64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32	520000–52FFFF 530000–53FFFF 540000–53FFFF 550000–55FFFF 560000–56FFFF 570000–57FFFF 580000–58FFFF 580000–58FFFF 5A0000–58FFFF 550000–50FFFF 550000–50FFFF 550000–55FFFF	290000–297FFF 298000–29FFFF 2A0000–2A7FFF 2A8000–2A7FFF 2B8000–2B7FFF 2B8000–2B7FFF 2C0000–2C7FFF 2C8000–2C7FFF 2D8000–2D7FFF 2D8000–2D7FFF 2E8000–2E7FFF 2E8000–2E7FFF 2F8000–2F7FFF
SA82           SA83           SA83           SA84           SA85           SA86           SA85           SA86           SA87           SA88           SA87           SA88           SA89           SA90           SA91           SA92           SA93           SA94           SA93           SA94           SA95           SA95           SA96           SA97           SA98           SA99           SA100           SA100           SA101           SA102           SA103           SA104           SA105           SA106           SA107	1010011xxx 1010100xxx 1010101xxx 1010110xxx 1010111xxx 1011000xxx 1011001xxx 1011010xxx 1011010xxx 1011101xxx 1011101xxx 1011110xxx 1011110xxx 1011111xxx 1011111xxx 1011111xxx 100000xxx 1100001xxx	64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32	530000–53FFFF           540000–54FFFF           550000–55FFFF           560000–56FFFF           570000–57FFFF           580000–58FFFF           590000–59FFFF           5A0000–50FFFF           5A0000–50FFFF           550000–50FFFF	298000–29FFFF 2A0000–2A7FFF 2A8000–2A7FFF 2B0000–2B7FFF 2B8000–2B7FFF 2C0000–2C7FFF 2C8000–2C7FFF 2D8000–2D7FFF 2D8000–2D7FFF 2E8000–2E7FFF 2F0000–2F7FFF 2F8000–2F7FFF
SA84           SA85           SA86           SA86           SA87           SA88           SA88           SA87           SA88           SA87           SA88           SA89           SA90           SA91           SA92           SA93           SA94           SA95           SA94           SA95           SA96           SA97           SA98           SA99           SA98           SA91           SA93           SA94           SA95           SA94           SA95           SA95           SA96           SA97           SA98           SA99           SA100           SA101           SA102           SA103           SA104           SA105           SA106           SA107	1010100xxx 1010101xxx 1010110xxx 1010111xxx 101000xxx 1011001xxx 1011010xxx 1011010xxx 1011101xxx 1011101xxx 1011110xxx 1011110xxx 10111110xxx 10111111xxx 100000xxx 1100001xxx 1100010xxx	64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32	540000–54FFFF         550000–55FFFF         560000–56FFFF         570000–57FFFF         580000–58FFFF         590000–59FFFF         5A0000–50FFFF         5B0000–50FFFF         5C0000–50FFFF         5D0000–50FFFF         5D0000–50FFFF         5E0000–50FFFF         5E0000–50FFFF         5F0000–50FFFF	2A0000–2A7FFF 2A8000–2A7FFF 2B0000–2B7FFF 2B8000–2B7FFF 2C0000–2C7FFF 2C8000–2C7FFF 2D0000–2D7FFF 2D8000–2D7FFF 2E8000–2E7FFF 2E8000–2E7FFF 2F8000–2F7FFF
PPB 21         SA85           SA85         SA86           SA87         SA87           SA88         SA89           PPB 22         SA90           SA91         SA91           SA92         SA93           PPB 23         SA93           SA95         SA94           SA95         SA95           SA96         SA97           SA98         SA99           PPB 24         SA93           SA95         SA94           SA95         SA95           SA94         SA95           SA95         SA94           SA95         SA95           SA101         SA102           SA100         SA101           SA102         SA103           SA103         SA104           SA105         SA106           SA106         SA107	1010101xxx 1010110xxx 1010111xxx 1011000xxx 1011001xxx 1011010xxx 1011010xxx 1011101xxx 1011101xxx 1011110xxx 1011110xxx 1011111xxx 1011111xxx 100000xxx 1100001xxx 1100010xxx	64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32	550000-55FFFF           560000-56FFFF           570000-57FFFF           580000-58FFFF           590000-59FFFF           5A0000-5AFFFF           5B0000-5BFFFF           5C0000-5CFFFF           5D0000-5DFFFF           5E0000-5EFFFF           5F0000-5FFFF	2A8000–2AFFFF 2B0000–2B7FFF 2B8000–2BFFFF 2C0000–2C7FFF 2C8000–2C7FFF 2D0000–2D7FFF 2D8000–2D7FFF 2E8000–2E7FFF 2E8000–2E7FFF 2F8000–2F7FFF
PPB 21         SA86           SA87         SA87           SA87         SA87           SA87         SA87           SA88         SA89           SA90         SA91           SA91         SA92           SA93         SA93           SA94         SA95           SA95         SA96           SA97         SA98           SA98         SA99           SA99         SA100           SA100         SA101           SA102         SA103           SA103         SA104           SA105         SA106           SA106         SA107	1010110xxx 1010111xxx 1011000xxx 1011001xxx 1011010xxx 1011010xxx 1011101xxx 1011101xxx 1011110xxx 1011110xxx 1011111xxx 1011111xxx 100000xxx 1100001xxx 1100010xxx	64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32	560000–56FFFF           570000–57FFFF           580000–58FFFF           590000–59FFFF           5A0000–50FFFF           5B0000–50FFFF           5C0000–50FFFF           5D0000–50FFFF           5E0000–50FFFF           5E0000–50FFFF           5E0000–50FFFF           5E0000–50FFFF           5F0000–50FFFF	2B0000–2B7FFF 2B8000–2BFFFF 2C0000–2C7FFF 2C8000–2CFFFF 2D0000–2D7FFF 2D8000–2DFFFF 2E8000–2E7FFF 2E8000–2EFFFF 2F8000–2F7FFF
SA86           SA87           SA88           SA89           SA90           SA91           SA92           SA93           SA94           SA95           SA96           SA97           SA98           SA94           SA95           SA96           SA97           SA98           SA99           SA100           SA101           SA102           SA103           SA104           SA105           SA106           SA107	1010111xxx 1011000xxx 1011001xxx 1011010xxx 1011010xxx 1011101xxx 1011101xxx 1011110xxx 1011110xxx 1011111xxx 100000xxx 1100001xxx 1100010xxx	64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32	570000–57FFFF 580000–58FFFF 590000–59FFFF 5A0000–5AFFFF 5B0000–5BFFFF 5C0000–5CFFFF 5D0000–5DFFFF 5E0000–5EFFFF 5F0000–5FFFFF	2B8000–2BFFFF 2C0000–2C7FFF 2C8000–2CFFFF 2D0000–2D7FFF 2D8000–2D7FFF 2E0000–2E7FFF 2E8000–2E7FFF 2F0000–2F7FFF 2F8000–2FFFFF
SA88           SA89           SA90           SA91           SA92           SA93           SA94           SA95           SA95           SA95           SA96           SA97           SA98           SA99           SA96           SA97           SA98           SA99           SA100           SA101           SA102           SA103           SA104           SA105           SA106           SA107	1011000xxx 1011001xxx 1011010xxx 1011011xxx 1011100xxx 1011101xxx 1011110xxx 1011110xxx 1011111xxx 100000xxx 1100001xxx 1100010xxx	64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32	580000–58FFFF 590000–59FFFF 5A0000–5AFFFF 5B0000–5BFFFF 5C0000–5CFFFF 5D0000–5DFFFF 5E0000–5EFFFF 5F0000–5FFFFF	2C0000-2C7FFF 2C8000-2CFFFF 2D0000-2D7FFF 2D8000-2DFFFF 2E0000-2E7FFF 2E8000-2EFFFF 2F0000-2F7FFF 2F8000-2FFFFF
PPB 22         SA89           SA90         SA91           SA91         SA92           PPB 23         SA93           SA94         SA95           SA95         SA95           PPB 24         SA96           SA97         SA98           SA98         SA99           PPB 24         SA96           SA97         SA98           SA99         SA100           SA100         SA101           SA102         SA103           PPB 26         SA105           SA106         SA107	1011001xxx 1011010xxx 1011011xxx 1011100xxx 1011101xxx 1011110xxx 10111110xxx 1011111xxx 1100000xxx 1100001xxx 1100010xxx	64/32 64/32 64/32 64/32 64/32 64/32 64/32 64/32	590000–59FFFF           5A0000–5AFFFF           5B0000–5BFFFF           5C0000–5CFFFF           5D0000–5DFFFF           5E0000–5EFFFF           5F0000–5FFFFF	2C8000–2CFFFF 2D0000–2D7FFF 2D8000–2DFFFF 2E0000–2E7FFF 2E8000–2EFFFF 2F0000–2F7FFF 2F8000–2FFFFF
PPB 22         SA90           SA91         SA91           SA92         SA93           PPB 23         SA93           SA94         SA94           SA95         SA96           SA97         SA98           SA98         SA99           SA99         SA100           SA101         SA102           SA102         SA103           PPB 26         SA105           SA106         SA107	1011010xxx 1011011xxx 1011100xxx 1011101xxx 1011110xxx 10111110xxx 10111111xxx 1100000xxx 1100001xxx 1100010xxx	64/32 64/32 64/32 64/32 64/32 64/32 64/32	5A0000–5AFFFF 5B0000–5BFFFF 5C0000–5CFFFF 5D0000–5DFFFF 5E0000–5EFFFF 5F0000–5FFFFF	2D0000–2D7FFF 2D8000–2DFFFF 2E0000–2E7FFF 2E8000–2EFFFF 2F0000–2F7FFF 2F8000–2FFFFF
SA90           SA91           SA92           SA93           SA94           SA95           SA95           SA96           SA97           SA98           SA99           SA96           SA97           SA98           SA99           SA100           SA101           SA102           SA103           PPB 26           SA105           SA106           SA107	1011011xxx 1011100xxx 1011101xxx 1011110xxx 10111110xxx 10111111xxx 1100000xxx 1100001xxx 1100010xxx	64/32 64/32 64/32 64/32 64/32 64/32	5B0000–5BFFFF 5C0000–5CFFFF 5D0000–5DFFFF 5E0000–5EFFFF 5F0000–5FFFFF	2D8000–2DFFFF 2E0000–2E7FFF 2E8000–2EFFFF 2F0000–2F7FFF 2F8000–2FFFFF
SA92           SA93           SA94           SA95           SA96           SA97           SA98           SA99           SA99           SA99           SA99           SA100           SA101           SA102           SA103           SA104           SA103           SA104           SA105           SA106           SA107	1011100xxx 1011101xxx 1011110xxx 1011111xxx 100000xxx 1100001xxx 1100010xxx	64/32 64/32 64/32 64/32 64/32	5C0000–5CFFFF 5D0000–5DFFFF 5E0000–5EFFFF 5F0000–5FFFFF	2E0000–2E7FFF 2E8000–2EFFFF 2F0000–2F7FFF 2F8000–2FFFFF
SA93           SA94           SA95           SA95           SA96           SA97           SA98           SA99           SA99           SA100           SA101           SA102           SA103           SA104           SA105           SA106           SA107	1011101xxx 1011110xxx 1011111xxx 1100000xxx 1100001xxx 1100010xxx	64/32 64/32 64/32 64/32	5D0000–5DFFFF 5E0000–5EFFFF 5F0000–5FFFFF	2E8000–2EFFFF 2F0000–2F7FFF 2F8000–2FFFFF
PPB 23 SA94 SA95 SA96 SA97 SA98 SA99 SA99 SA100 SA100 SA101 SA102 SA103 SA104 SA105 SA106 SA107	1011110xxx 1011111xxx 1100000xxx 1100001xxx 1100010xxx	64/32 64/32 64/32	5E0000–5EFFFF 5F0000–5FFFFF	2F0000–2F7FFF 2F8000–2FFFFF
SA94           SA95           SA96           SA97           SA98           SA99           SA99           SA100           SA101           SA102           SA103           PPB 26           SA105           SA107	1011111xxx 1100000xxx 1100001xxx 1100010xxx	64/32 64/32	5F0000–5FFFFF	2F8000–2FFFFF
SA96           SA97           SA98           SA99           SA99           SA100           SA101           SA102           SA103           SA104           SA105           SA106           SA107	1100000xxx 1100001xxx 1100010xxx	64/32		
SA97           SA98           SA99           SA100           SA100           SA101           SA102           SA103           PPB 26           SA105           SA106	1100001xxx 1100010xxx		600000-60FFFF	
PPB 24 SA98 SA99 SA100 SA100 SA101 SA102 SA103 SA104 SA105 SA106 SA107	1100010xxx	64/32		300000–307FFF
SA98           SA99           SA100           SA100           SA101           SA102           SA103           PPB 26           SA105           SA106           SA107			610000-61FFFF	308000-30FFFF
PPB 25 SA100 SA101 SA102 SA103 SA104 SA105 SA106 SA107		64/32	620000–62FFFF	310000–317FFF
PPB 25 SA101 SA102 SA103 SA103 SA104 SA105 SA106 SA107	1100011xxx	64/32	630000–63FFFF	318000–31FFFF
PPB 25 SA102 SA103 SA104 SA104 SA105 SA106 SA106 SA107	1100100xxx	64/32	640000–64FFFF	320000–327FFF
SA102           SA103           SA104           SA105           SA106           SA107	1100101xxx	64/32	650000-65FFFF	328000-32FFFF
PPB 26 SA104 SA105 SA106 SA107	1100110xxx	64/32	660000-66FFFF	330000–337FFF
PPB 26 SA105 SA106 SA107	1100111xxx	64/32	670000–67FFFF	338000-33FFFF
PPB 26 SA106 SA107	1101000xxx	64/32	680000–68FFFF	340000–347FFF
SA106 SA107	1101001xxx	64/32	690000-69FFFF	348000–34FFFF
	1101010xxx	64/32	6A0000-6AFFFF	350000–357FFF
SA108	1101011xxx	64/32	6B0000-6BFFFF	358000-35FFFF
	1101100xxx	64/32	6C0000-6CFFFF	360000–367FFF
SA109	1101101xxx	64/32	6D0000-6DFFFF	368000–36FFFF
PPB 27 SA110	1101110xxx	64/32	6E0000-6EFFFF	370000–377FFF
SA111	1101111xxx	64/32	6F0000–6FFFFF	378000–37FFFF
SA112	1110000xxx	64/32	700000–70FFFF	380000–387FFF
SA113	1110001xxx	64/32	710000–71FFFF	388000–38FFFF
PPB 28 SA114	1110010xxx	64/32	720000–72FFFF	390000–397FFF
SA115	1110011xxx	64/32	730000–73FFFF	398000–39FFFF
SA116	1110100xxx	64/32	740000–74FFFF	3A0000–3A7FFF
SA117	1110101xxx	64/32	750000–75FFFF	3A8000–3AFFFF
PPB 29 SA118	1110110xxx	64/32	760000–76FFFF	3B0000–3B7FFF
SA119	1110111xxx	64/32	770000–77FFFF	3B8000–3BFFFF
PPB 30 SA120	1111000xxx	64/32	780000–78FFFF	3C0000-3C7FFF
SA121		64/32	790000–79FFFF	3C8000-3CFFFF
SA122	1111001xxx	64/32	7A0000–7AFFFF	3D0000-3D7FFF

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	SA123	1111011xxx	64/32	7B0000–7BFFFF	3D8000–3DFFFF
PPB 31	SA124	1111100xxx	64/32	7C0000-7CFFFF	3E0000-3E7FFF
PPB 32	SA125	1111101xxx	64/32	7D0000–7DFFFF	3E8000–3EFFFF
PPB 33	SA126	1111110xxx	64/32	7E0000–7EFFFF	3F0000–3F7FFF
PPB 34	SA127	1111111000	8/4	7F0000–7F1FFF	3F8000–3F8FFF
PPB 35	SA128	1111111001	8/4	7F2000–7F3FFF	3F9000–3F9FFF
PPB 36	SA129	1111111010	8/4	7F4000–7F5FFF	3FA000–3FAFFF
PPB 37	SA130	1111111011	8/4	7F6000–7F7FFF	3FB000–3FBFFF
PPB 38	SA131	1111111100	8/4	7F8000–7F9FFF	3FC000–3FCFFF
PPB 39	SA132	1111111101	8/4	7FA000–7FBFFF	3FD000–3FDFFF
PPB 40	SA133	1111111110	8/4	7FC000–7FDFFF	3FE000–3FEFFF
PPB 41	SA134	1111111111	8/4	7FE000–7FFFFF	3FF000–3FFFFF

## Table 3C. Bottom Boot Sector / Persistent Protection Sector Group Address Tables (EN29GL064B)

PPB Group	Sector	A21 – A12	Sector Size (Kbytes / Kwords)	Address Range (h) Byte mode (x8)	Address Range (h) Word Mode (x16)
PPB 0	SA0	0000000000	8/4	000000-001FFF	000000-000FFF
PPB 1	SA1	000000001	8/4	002000-003FFF	001000-001FFF
PPB 2	SA2	000000010	8/4	004000-005FFF	002000-002FFF
PPB 3	SA3	000000011	8/4	006000-007FFF	003000-003FFF
PPB 4	SA4	000000100	8/4	008000-009FFF	004000-004FFF
PPB 5	SA5	000000101	8/4	00A000-00BFFF	005000-005FFF
PPB 6	SA6	0000000110	8/4	00C000-00DFFF	006000-006FFF
PPB 7	SA7	0000000111	8/4	00E000-00FFFF	007000–007FFF
PPB 8	SA8	0000001xxx	64/32	010000-01FFFF	008000-00FFFF
PPB 9	SA9	0000010xxx	64/32	020000-02FFFF	010000–017FFF
PPB 10	SA10	0000011xxx	64/32	030000-03FFFF	018000-01FFFF
	SA11	0000100xxx	64/32	040000-04FFFF	020000-027FFF
	SA12	0000101xxx	64/32	050000–05FFFF	028000-02FFFF
PPB 11	SA13	0000110xxx	64/32	060000-06FFFF	030000-037FFF
	SA14	0000111xxx	64/32	070000–07FFFF	038000-03FFFF
	SA15	0001000xxx	64/32	080000–08FFFF	040000–047FFF
PPB 12	SA16	0001001xxx	64/32	090000-09FFFF	048000–04FFFF
FFD 12	SA17	0001010xxx	64/32	0A0000-0AFFFF	050000-057FFF
	SA18	0001011xxx	64/32	0B0000-0BFFFF	058000-05FFFF
	SA19	0001100xxx	64/32	0C0000-0CFFFF	060000-067FFF
PPB 13	SA20	0001101xxx	64/32	0D0000-0DFFFF	068000-06FFFF
PPB 13	SA21	0001110xxx	64/32	0E0000-0EFFFF	070000–077FFF
	SA22	0001111xxx	64/32	0F0000-0FFFFF	078000–07FFFF
	SA23	0010000xxx	64/32	100000–10FFFF	080000–087FFF
PPB 14	SA24	0010001xxx	64/32	110000–11FFFF	088000–08FFFF
	SA25	0010010xxx	64/32	120000–12FFFF	090000–097FFF
	SA26	0010011xxx	64/32	130000–13FFFF	098000-09FFFF

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-	SA27	0010100xxx	64/32	140000–14FFFF	0A0000-0A7FFF
PPB 15	SA28	0010101xxx	64/32	150000–15FFFF	0A8000-0AFFFF
PPB 15	SA29	0010110xxx	64/32	160000–16FFFF	0B0000-0B7FFF
	SA30	0010111xxx	64/32	170000–17FFFF	0B8000-0BFFFF
	SA31	0011000xxx	64/32	180000–18FFFF	0C0000-0C7FFF
PPB 16	SA32	0011001xxx	64/32	190000–19FFFF	0C8000-0CFFFF
	SA33	0011010xxx	64/32	1A0000–1AFFFF	0D0000-0D7FFF
	SA34	0011011xxx	64/32	1B0000–1BFFFF	0D8000-0DFFFF
	SA35	0011100xxx	64/32	1C0000-1CFFFF	0E0000-0E7FFF
	SA36	0011101xxx	64/32	1D0000–1DFFFF	0E8000-0EFFFF
PPB 17	SA37	0011110xxx	64/32	1E0000–1EFFFF	0F0000-0F7FFF
	SA38	0011111xxx	64/32	1F0000–1FFFFF	0F8000-0FFFFF
	SA39	0100000xxx	64/32	200000–20FFFF	100000–107FFF
	SA40	0100001xxx	64/32	210000-21FFFF	108000-10FFFF
PPB 18	SA41	0100010xxx	64/32	220000-22FFFF	110000–117FFF
	SA42	0100011xxx	64/32	230000–23FFFF	118000–11FFFF
	SA43	0100100xxx	64/32	240000–24FFFF	120000–127FFF
	SA44	0100101xxx	64/32	250000–25FFFF	128000–12FFFF
PPB 19	SA45	0100110xxx	64/32	260000–26FFFF	130000–137FFF
-	SA46	0100111xxx	64/32	270000–27FFFF	138000–13FFFF
	SA47	0101000xxx	64/32	280000–28FFFF	140000–147FFF
PPB 20	SA48	0101001xxx	64/32	290000–29FFFF	148000–14FFFF
	SA49	0101010xxx	64/32	2A0000–2AFFFF	150000–157FFF
	SA50	0101011xxx	64/32	2B0000-2BFFFF	158000–15FFFF
	SA51	0101100xxx	64/32	2C0000-2CFFFF	160000–167FFF
	SA52	0101101xxx	64/32	2D0000-2DFFFF	168000–16FFFF
PPB 21	SA53	0101110xxx	64/32	2E0000-2EFFFF	170000–177FFF
	SA54	0101111xxx	64/32	2F0000–2FFFFF	178000–17FFFF
	SA55	0110000xxx	64/32	300000-30FFFF	180000–187FFF
	SA56	0110001xxx	64/32	310000–31FFFF	188000–18FFFF
PPB 22 -	SA57	0110010xxx	64/32	320000-32FFFF	190000–197FFF
	SA58	0110011xxx	64/32	330000–33FFFF	198000–19FFFF
	SA59	0110100xxx	64/32	340000–34FFFF	1A0000–1A7FFF
PPB 23 -	SA60	0110101xxx	64/32	350000–35FFFF	1A8000–1AFFFF
	SA61	0110110xxx	64/32	360000–36FFFF	1B0000–1B7FFF
	SA62	0110111xxx	64/32	370000–37FFFF	1B8000–1BFFFF
	SA63	0111000xxx	64/32	380000–38FFFF	1C0000-1C7FFF
	SA64	0111001xxx	64/32	390000–39FFFF	1C8000-1CFFFF
PPB 24	SA65	0111010xxx	64/32	3A0000–3AFFFF	1D0000–1D7FFF
	SA66	0111011xxx	64/32	3B0000–3BFFFF	1D8000–1DFFFF
PPB 25	SA67	0111100xxx	64/32	3C0000-3CFFFF	1E0000-1E7FFF
	SA68	0111101xxx	64/32	3D0000–3DFFFF	1E8000–1EFFFF
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	SA70	0111111xxx	64/32	3F0000–3FFFFF	1F8000–1FFFFF
	SA70	1000000xxx	64/32	400000-40FFFF	200000–207FFF
PPB 26	SA71 SA72	1000001xxx	64/32	410000–41FFFF	208000–20FFFF
	SA72 SA73	1000001xxx	64/32	420000–42FFFF	210000–217FFF
	SA73	1000010XXX	64/32	420000–42FFFF 430000–43FFFF	218000–217FFF
	SA74 SA75	1000011XXX 1000100XXX	64/32	440000–44FFFF	220000–227FFF
			64/32		
PPB 27	SA76	1000101xxx	64/32	450000–45FFFF 460000–46FFFF	228000–22FFFF 230000–237FFF
	SA77	1000110xxx			
	SA78	1000111xxx	64/32	470000-47FFFF	238000-23FFFF
Í	SA79	1001000xxx	64/32	480000-48FFFF	240000-247FFF
PPB 28	SA80	1001001xxx	64/32	490000-49FFF	248000-24FFFF
	SA81	1001010xxx	64/32	4A0000-4AFFFF	250000-257FFF
	SA82	1001011xxx	64/32	4B0000-4BFFFF	258000-25FFFF
	SA83	1001100xxx	64/32	4C0000-4CFFFF	260000–267FFF
PPB 29	SA84	1001101xxx	64/32	4D0000-4DFFFF	268000–26FFFF
	SA85	1001110xxx	64/32	4E0000–4EFFFF	270000–277FFF
	SA86	1001111xxx	64/32	4F0000–4FFFFF	278000–27FFFF
	SA87	1010000xxx	64/32	500000-50FFFF	280000–287FFF
PPB 30	SA88	1010001xxx	64/32	510000–51FFFF	288000–28FFFF
	SA89	1010010xxx	64/32	520000–52FFFF	290000–297FFF
	SA90	1010011xxx	64/32	530000–53FFFF	298000–29FFFF
	SA91	1010100xxx	64/32	540000–54FFFF	2A0000–2A7FFF
PPB 31	SA92	1010101xxx	64/32	550000-55FFFF	2A8000–2AFFFF
	SA93	1010110xxx	64/32	560000-56FFFF	2B0000–2B7FFF
	SA94	1010111xxx	64/32	570000–57FFFF	2B8000–2BFFFF
	SA95	1011000xxx	64/32	580000–58FFFF	2C0000-2C7FFF
PPB 32	SA96	1011001xxx	64/32	590000–59FFFF	2C8000-2CFFFF
110.02	SA97	1011010xxx	64/32	5A0000–5AFFFF	2D0000-2D7FFF
	SA98	1011011xxx	64/32	5B0000–5BFFFF	2D8000–2DFFFF
	SA99	1011100xxx	64/32	5C0000-5CFFFF	2E0000-2E7FFF
PPB 33	SA100	1011101xxx	64/32	5D0000-5DFFFF	2E8000-2EFFFF
FFB 55	SA101	1011110xxx	64/32	5E0000-5EFFFF	2F0000–2F7FFF
	SA102	1011111xxx	64/32	5F0000-5FFFFF	2F8000–2FFFFF
	SA103	1100000xxx	64/32	600000-60FFFF	300000–307FFF
PPB 34	SA104	1100001xxx	64/32	610000–61FFFF	308000-30FFFF
FFD 34	SA105	1100010xxx	64/32	620000–62FFFF	310000–317FFF
	SA106	1100011xxx	64/32	630000–63FFFF	318000–31FFFF
	SA107	1100100xxx	64/32	640000–64FFFF	320000–327FFF
	SA108	1100101xxx	64/32	650000–65FFFF	328000–32FFFF
PPB 35	SA109	1100110xxx	64/32	660000–66FFFF	330000–337FFF
	SA110	1100111xxx	64/32	670000–67FFFF	338000–33FFFF
PPB 36	SA111	1101000xxx	64/32	680000–68FFFF	340000–347FFF
	SA112	1101001xxx	64/32	690000–69FFFF	348000–34FFFF

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	SA113 11010		64/32	6A0000–6AFFFF	350000–357FFF
	SA114	1101011xxx	64/32	6B0000–6BFFFF	358000–35FFFF
	SA115	1101100xxx	64/32	6C0000-6CFFFF	360000–367FFF
PPB 37	SA116	1101101xxx	64/32	6D0000–6DFFFF	368000–36FFFF
FFD 37	SA117	1101110xxx	64/32	6E0000-6EFFFF	370000–377FFF
	SA118	1101111xxx	64/32	6F0000–6FFFFF	378000–37FFFF
	SA119	1110000xxx	64/32	700000–70FFFF	380000–387FFF
PPB 38	SA120	1110001xxx	64/32	710000–71FFFF	388000–38FFFF
FFD 30	SA121	1110010xxx	64/32	720000–72FFFF	390000–397FFF
	SA122	1110011xxx	64/32	730000–73FFFF	398000–39FFFF
	SA123	1110100xxx	64/32	740000–74FFFF	3A0000–3A7FFF
PPB 39	SA124	1110101xxx	64/32	750000–75FFFF	3A8000–3AFFFF
FFD 39	SA125	1110110xxx	64/32	760000–76FFFF	3B0000–3B7FFF
	SA126	1110111xxx	64/32	770000–77FFFF	3B8000–3BFFFF
	SA127	1111000xxx	64/32	780000–78FFFF	3C0000-3C7FFF
PPB 40	SA128	1111001xxx	64/32	790000–79FFFF	3C8000-3CFFFF
PPB 40	SA129	1111010xxx	64/32	7A0000–7AFFFF	3D0000-3D7FFF
	SA130	1111011xxx	64/32	7B0000–7BFFFF	3D8000–3DFFFF
	SA131	1111100xxx	64/32	7C0000-7CFFFF	3E0000-3E7FFF
PPB 41	SA132	1111101xxx	64/32	7D0000–7DFFFF	3E8000–3EFFFF
	SA133	1111110xxx	64/32	7E0000–7EFFFF	3F0000–3F7FFF
	SA134	11111111xxx	64/32	7F0000–7FFFFF	3F8000–3FFFFF

### **Table 4. Device OPERATING MODES**

### 64M FLASH USER MODE TABLE

								DQ8-	DQ15
Operation	CE#	OE#	WE#	RESET #	WP#/AC C	A0- A21	DQ0- DQ7	BYTE# = V <sub>IH</sub>	BYTE# = V <sub>IL</sub> .
Read	L	L	Н	Н	L/H	A <sub>IN</sub>	D <sub>OUT</sub>	D <sub>OUT</sub>	DQ8-
Write	L	Н	L	Н	(Note 1)	A <sub>IN</sub>	D.IN.	D <sub>IN</sub>	DQ14=
Accelerated Program	L	н	L	Н	V <sub>HH</sub>	A <sub>IN</sub>	D <sub>IN</sub> .	D. <sub>IN</sub> .	High-Z, DQ15 = A-1
CMOS Standby	V <sub>cc</sub> ±0.3V	х	х	V <sub>cc</sub> ±0.3V	н	х	High-Z	High-Z	High-Z
Output Disable	L	Н	Н	Н	L/H	Х	High-Z	High-Z	High-Z
Hardware Reset	Х	Х	Х	L	L/H	Х	High-Z	High-Z	High-Z

#### Notes:

1. Addresses are A21:A0 in word mode; A21:A-1 in byte mode.

2. If WP# = VIL, on the outermost sector remains protected. If WP# = VIH, the outermost sector is unprotected. WP# has an internal pull-up; when unconnected, WP# is at VIH. All sectors are unprotected when shipped from the factory (The Secured Silicon Sector can be factory protected depending on version ordered.) 3. DIN or DOUT as required by command sequence, data polling, or sector protect algorithm.

#### Legend

L = Logic Low = VIL, H = Logic High = VIH, VHH = 8.5–9.5V, X = Don't Care, AIN = Address In, DIN = Data In, DOUT = Data Out

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## **USER MODE DEFINITIONS**

#### Word / Byte Configuration

The BYTE# pin controls whether the device data I/O pins operate in the byte or word configuration. If the

BYTE# pin is set at logic '1', the device is in word configuration, DQ0-DQ15 are active and controlled by CE# and OE#.

If the BYTE# pin is set at logic '0', the device is in byte configuration, and only data I/O pins DQ0-DQ7 are active and controlled by CE# and OE#. The data I/O pins DQ8-DQ14 are tri-stated, and the DQ15 pin is used as an input for the LSB (A-1) address function.

#### Read

All memories require access time to output array data. In a read operation, data is read from one memory location at a time. Addresses are presented to the device in random order, and the propagation delay through the device causes the data on its outputs to arrive with the address on its inputs.

The device defaults to reading array data after device power-up or hardware reset. To read data from the memory array, the system must first assert a valid address on A21-A0, while driving OE# and CE# to VIL. WE# must remain at VIH. All addresses are latched on the falling edge of CE#. Data will appear on DQ15-DQ0 after address access time (tACC), which is equal to the delay from stable addresses to valid output data.The OE# signal must be driven to VIL. Data is output on DQ15-DQ0 pins after the access time (tOE) has elapsed from the falling edge of OE#, assuming the tACC access time has been meet.

#### Page Read Mode

The device is capable of fast page mode read and is compatible with the page mode Mask ROM read operation. This mode provides faster read access speed for random locations within a page. The page size of the device is 8 words/16 bytes. The appropriate page is selected by the higher address bits A21-A3. Address bits A2-A0 in word mode (A2 to A-1 in byte mode) determine the specific word within a page. The microprocessor supplies the specific word location.

The random or initial page access is equal to tACC or tCE and subsequent page read accesses (as long as the locations specified by the microprocessor falls within that page) is equivalent to tPACC. When CE# is deasserted and reasserted for a subsequent access, the access time is tACC or tCE. Fast page mode accesses are obtained by keeping the "read-page addresses" constant and changing the "intra-read page" addresses.

#### Autoselect

The Autoselect mode provides manufacturer ID, Device identification, and sector protection information, through identifier codes output from the internal register (separate from the memory array) on DQ7-DQ0.

The device only support to use autoselect command to access autoselect codes. It does not support to apply VID on address pin A9.

- The Autoselect command sequence may be written to an address within a sector that is either in the read or **erase-suspend-read mode.**
- The Autoselect command may not be written while the device is actively programming or erasing.
- The system must write the reset command to return to the read mode (or erase-suspend-read mode if the sector was previously in Erase Suspend).
- When verifying sector protection, the sector address must appear on the appropriate highest order address bits. The remaining address bits are don't care and then read the corresponding identifier code on DQ15-DQ0.

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### **Program/Erase Operations**

These devices are capable of several modes of programming and or erase operations which are described in detail in the following sections.

During a write operation, the system must drive CE# and WE# to VIL and OE# to VIH when providing address, command, and data. Addresses are latched on the last falling edge of WE# or CE#, while data is latched on the 1st rising edge of WE# or CE#.

Note the following:

- When the Embedded Program algorithm is complete, the device returns to the read mode.
- The system can determine the status of the program operation by reading the DQ status bits. Refer to the Write Operation Status on page 28 for information on these status bits.
- An "0" cannot be programmed back to a "1." A succeeding read shows that the data is still "0."
- Only erase operations can convert a "0" to a "1."
- Any commands written to the device during the Embedded Program/Erase are ignored except the Suspend commands.
- Secured Silicon Sector, Autoselect, and CFI functions are unavailable when a program operation is in progress.
- A hardware reset and/or power removal immediately terminates the Program/Erase operation and the Program/Erase command sequence should be reinitiated once the device has returned to the read mode to ensure data integrity.
- Programming is allowed in any sequence and across sector boundaries for single word programming operation.
- Programming to the same word address multiple times without intervening erases is permitted.

#### Single Word Programming

Single word programming mode is one method of programming the Flash. In this mode, four Flash command write cycles are used to program an individual Flash address. The data for this programming operation could be 8 or 16-bits wide.

While the single word programming method is supported by most devices, in general Single Word Programming is not recommended for devices that support Write Buffer Programming.

When the Embedded Program algorithm is complete, the device then returns to the read mode and addresses are no longer latched. The system can determine the status of the program operation by reading the DQ status bits.

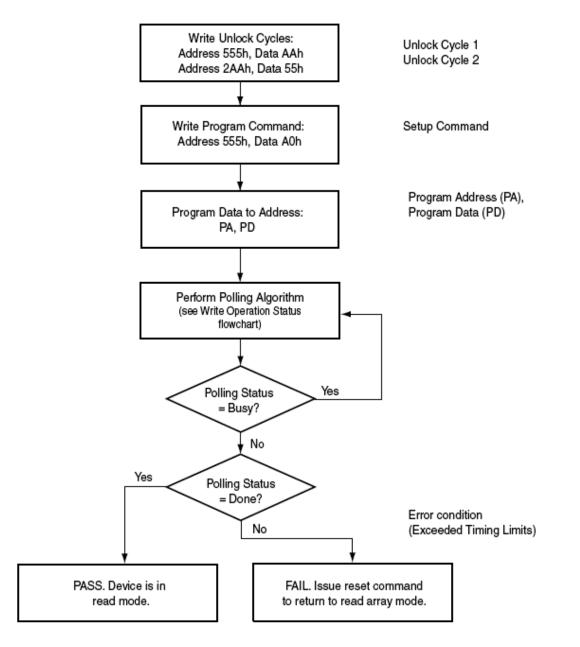
- During programming, any command (except the Suspend Program command) is ignored.
- The Secured Silicon Sector, Autoselect, and CFI functions are unavailable when a program operation is in progress.
- A hardware reset immediately terminates the program operation. The program command sequence should be reinitiated once the device has returned to the read mode, to ensure data integrity.
- Programming to the same address multiple times continuously (for example, "walking" a bit within a word) is permitted.

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## Figure 4. Single Word Program



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#### Write Buffer Programming

Write Buffer Programming allows the system to write a maximum of 16 words in one programming operation. This results in a faster effective word programming time than the standard "word" programming algorithms. The Write Buffer Programming command sequence is initiated by first writing two unlock cycles. This is followed by a third write cycle containing the Write Buffer Load command written at the Sector Address in which programming occurs. At this point, the system writes the number of "word locations minus 1" that are loaded into the page buffer at the Sector Address in which programming occurs. This tells the device how many write buffer addresses are loaded with data and therefore when to expect the "Program Buffer to Flash" confirm command. The number of locations to program cannot exceed the size of the write buffer or the operation aborts. (Number loaded = the number of locations to program minus 1. For example, if the system programs 6 address locations, then 05h should be written to the device.)

The system then writes the starting address/data combination. This starting address is the first address/data pair to be programmed, and selects the "write-buffer-page" address. All subsequent address/data pairs must fall within the elected-write-buffer-page.

The "write-buffer-page" is selected by using the addresses A21–A4.

The "write-buffer-page" addresses must be the same for all address/data pairs loaded into the write buffer. (This means Write Buffer Programming cannot be performed across multiple "write-buffer-pages." This also means that Write Buffer Programming cannot be performed across multiple sectors. If the system attempts to load programming data outside of the selected "write-buffer-page", the operation ABORTs.)

After writing the Starting Address/Data pair, the system then writes the remaining address/data pairs into the write buffer.

Note that if a Write Buffer address location is loaded multiple times, the "address/data pair" counter is decremented for every data load operation. Also, the last data loaded at a location before the "Program Buffer to Flash" confirm command is the data programmed into the device. It is the software's responsibility to comprehend ramifications of loading a write-buffer location more than once. The counter decrements for each data load operation, NOT for each unique write-buffer-address location. Once the specified number of write buffer locations have been loaded, the system must then write the "Program Buffer to Flash" command at the Sector Address. Any other address/data write combinations abort the Write Buffer Programming operation. The Write Operation Status bits should be used while monitoring the last address location loaded into the write buffer. This eliminates the need to store an address in memory because the system can load the last address location, issue the program confirm command at the last loaded address location, and then check the write operation status at that same address. DQ7, DQ6, DQ5, DQ2, and DQ1 should be monitored to determine the device status during Write Buffer Programming.

The write-buffer "embedded" programming operation can be suspended using the standard suspend/resume commands. Upon successful completion of the Write Buffer Programming operation, the device returns to READ mode.

The Write Buffer Programming Sequence is ABORTED under any of the following conditions:

- Load a value that is greater than the page buffer size during the "Number of Locations to Program" step.
- Write to an address in a sector different than the one specified during the Write-Buffer-Load command.
- Write an Address/Data pair to a different write-buffer-page than the one selected by the "Starting Address" during the "write buffer data loading" stage of the operation.
- Writing anything other than the Program to Buffer Flash Command after the specified number of "data load" cycles.

The ABORT condition is indicated by DQ1 = 1, DQ7 = DATA# (for the "last address location loaded"), DQ6 = TOGGLE, DQ5 = 0. This indicates that the Write Buffer Programming Operation was ABORTED. Note that the Secured Silicon sector, autoselect, and CFI functions are unavailable when a program

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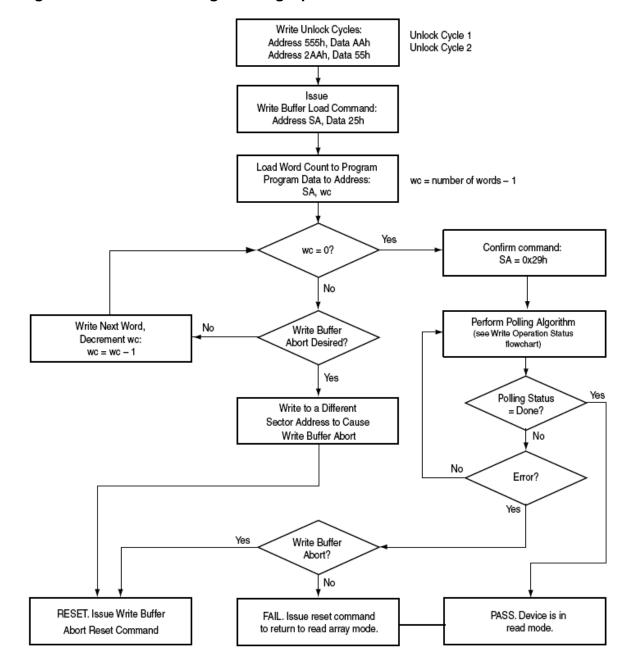


operation is in progress.

Write buffer programming is allowed in any sequence of memory (or address) locations. These flash devices are capable of handling multiple write buffer programming operations on the same write buffer address range without intervening erases.

Use of the write buffer is strongly recommended for programming when multiple words are to be programmed.

#### Figure 5. Write Buffer Programming Operation



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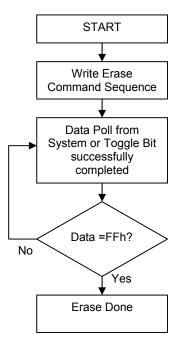
#### **Sector Erase**

Sector erase is a six bus cycle operation. The sector erase command sequence is initiated by writing two un-lock cycles, followed by a set-up command. Two additional unlock write cycles are then followed by the address of the sector to be erased, and the sector erase command. The Command Definitions table shows the address and data requirements for the sector erase command sequence.

Once the sector erase operation has begun, only the Sector Erase Suspend command is valid. All other commands are ignored. If there are several sectors to be erased, Sector Erase Command sequences must be issued for each sector. That is, only a sector address can be specified for each Sector Erase command. Users must issue another Sector Erase command for the next sector to be erased after the previous one is completed.

When the Embedded Erase algorithm is completed, the device returns to reading array data and addresses are no longer latched. The system can determine the status of the erase operation by using DQ7, DQ6, or DQ2. Refer to "Write Operation Status" for information on these status bits. Flowchart 4 illustrates the algorithm for the erase operation. Refer to the Erase/Program Operations tables in the "AC Characteristics" section for parameters, and to the Sector Erase Operations Timing diagram for timing waveforms.

#### Figure 6. Sector Erase Operation



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#### Chip Erase Command Sequence

Chip erase is a six-bus cycle operation as indicated by Table 13. These commands invoke the Embedded Erase algorithm, which does not require the system to preprogram prior to erase. The Embedded Erase algorithm automatically preprograms and verifies the entire memory to an all zero data pattern prior to electrical erase. After a successful chip erase, all locations of the chip contain FFFFh. The system is not required to provide any controls or timings during these operations.

When the Embedded Erase algorithm is complete, that sector returns to the read mode and addresses are no longer latched. The system can determine the status of the erase operation by using DQ7 or DQ6/DQ2. Refer to "Write Operation Status" for information on these status bits.

Any commands written during the chip erase operation are ignored. However, note that a hardware reset immediately terminates the erase operation. If that occurs, the chip erase command sequence should be reinitiated once that sector has returned to reading array data, to ensure the entire array is properly erased.

#### **Erase Suspend/Erase Resume Commands**

The Erase Suspend command allows the system to interrupt a sector erase operation and then read data from, or program data to, any sector not selected for erasure. The sector address is required when writing this command. This command is valid only during the sector erase operation. The Sector Erase Suspend command is ignored if written during the chip erase operation or Embedded Program algorithm. Addresses are don't-cares when writing the Sector Erase Suspend command.

When the Erase Suspend command is written during the sector erase operation, the device requires a maximum of 20 µs to suspend the erase operation.

After the erase operation has been suspended, the device enters the erase-suspend-read mode. The system can read data from or program data to any sector not selected for erasure. (The device "erase suspends" all sectors selected for erasure.) Reading at any address within erase-suspended sectors produces status information on DQ7-DQ0. The system can use DQ7, or DQ6, and DQ2 together, to determine if a sector is actively erasing or is erase-suspended.

After an erase-suspended program operation is complete, the device returns to the erase-suspend-read

mode. The system can determine the status of the program operation using write operation status bits, just as in the standard program operation.

In the erase-suspend-read mode, the system can also issue the Autoselect command sequence. Refer to Write Buffer Programming and the Autoselect for details.

To resume the sector erase operation, the system must write the Erase Resume command. The address of the erase-suspended sector is required when writing this command. Further writes of the Resume command are ignored. Another Erase Suspend command can be written after the chip has resumed erasing.

#### **Program Suspend/Program Resume Commands**

The Program Suspend command allows the system to interrupt an embedded programming operation or a "Write to Buffer" programming operation so that data can read from any non-suspended sector. When the Program Suspend command is written during a programming process, the device halts the programming operation within 15  $\mu$ s maximum (5  $\mu$ s typical) and updates the status bits. Addresses are "don't-cares" when writing the Program Suspend command.

After the programming operation has been suspended, the system can read array data from any nonsuspended sector. The Program Suspend command may also be issued during a programming operation while an erase is suspended. In this case, data may be read from any addresses not within a sector in Erase Suspend or Program Suspend. If a read is needed from the Secured Silicon Sector area, then user must use the proper command sequences to enter and exit this region.

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The system may also write the Autoselect Command Sequence when the device is in Program Suspend mode. The device allows reading Autoselect codes in the suspended sectors, since the codes are not stored in the memory array. When the device exits the Autoselect mode, the device reverts to Program Suspend mode, and is ready for another valid operation.

After the Program Resume command is written, the device reverts to programming. The system can determine the status of the program operation using the write operation status bits, just as in the standard program operation.

The system must write the Program Resume command (address bits are "don't care") to exit the Program Suspend mode and continue the programming operation. Further writes of the Program Resume command are ignored. Another Program Suspend command can be written after the device has resumed programming.

#### **Accelerated Program**

Accelerated single word programming and write buffer programming operations are enabled through the

WP#/ACC pin. This method is faster than the standard program command sequences.

If the system asserts  $V_{HH}$  on this input, the device automatically enters the Accelerated Program mode and uses the higher voltage on the input to reduce the time required for program operations. The system can then use the Write Buffer Load command sequence provided by the Accelerated Program mode. Note that if a "Write-to-Buffer-Abort Reset" is required while in Accelerated Program mode, the full 3-cycle RESET command sequence must be used to reset the device. Removing V<sub>HH</sub> from the ACC input, upon completion of the embedded program operation, returns the device to normal operation.

- Sectors must be unlocked prior to raising WP#/ACC to V<sub>HH</sub>.
- The WP#/ACC pin must not be at V<sub>HH</sub> for operations other than accelerated programming, or device damage may result.
- It is recommended that WP#/ACC apply V<sub>HH</sub> after power-up sequence is completed. In addition, it is
  recommended that WP#/ACC apply from V<sub>HH</sub> to VIH/VIL before powering down V<sub>CC</sub>.

### Write Operation Status

The device provides several bits to determine the status of a program or erase operation. The following subsections describe the function of DQ1, DQ2, DQ3, DQ5, DQ6, and DQ7.

#### DQ7: Data# Polling

The Data# Polling bit, DQ7, indicates to the host system whether an Embedded Program or Erase algorithm is in progress or completed, or whether the device is in Erase Suspend. Data# Polling is valid after the rising edge of the final WE# pulse in the command sequence. Note that the Data# Polling is valid only for the last word being programmed in the write-buffer-page during Write Buffer Programming. Reading Data# Polling status on any word other than the last word to be programmed in the write-buffer-page returns false status information.

During the Embedded Program algorithm, the device outputs on DQ7 the complement of the datum programmed to DQ7. This DQ7 status also applies to programming during Erase Suspend. When the Embedded Program algorithm is complete, the device outputs the datum programmed to DQ7. The system must provide the program address to read valid status information on DQ7. If a program address falls within a protected sector, Data# polling on DQ7 is active, then that sector returns to the read mode.

During the Embedded Erase Algorithm, Data# polling produces a "0" on DQ7. When the Embedded Erase algorithm is complete, or if the device enters the Erase Suspend mode, Data# Polling produces a "1" on DQ7. The system must provide an address within any of the sectors selected for erasure to read

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valid status information on DQ7.

After an erase command sequence is written, if all sectors selected for erasing are protected, Data# Polling on DQ7 is active for approximately 100 µs, then the device returns to the read mode. If not all selected sectors are protected, the Embedded Erase algorithm erases the unprotected sectors, and ignores the selected sectors that are protected. However, if the system reads DQ7 at an address within a protected sector, the status may not be valid.

Just prior to the completion of an Embedded Program or Erase operation, DQ7 may change asynchronously with DQ6-DQ0 while Output Enable (OE#) is asserted low. That is, the device may change from providing status information to valid data on DQ7. Depending on when the system samples the DQ7 output, it may read the status or valid data. Even if the device has completed the program or erase operation and DQ7 has valid data, the data outputs on DQ6-DQ0 may be still invalid. Valid data on DQ7-D00 appears on successive read cycles.

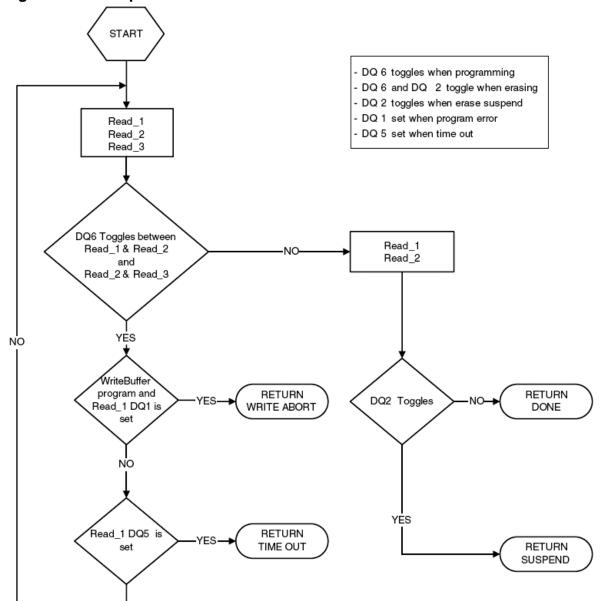


Figure 7. Write Operation Status Flowchart

### DQ6: Toggle Bit I

Toggle Bit I on DQ6 indicates whether an Embedded Program or Erase algorithm is in progress or complete, or whether the device has entered the Erase Suspend mode. Toggle Bit I may be read at any

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address, and is valid after the rising edge of the final WE# pulse in the command sequence (prior to the program or erase operation), and during the sector erase time-out.

During an Embedded Program or Erase algorithm operation, successive read cycles to any address that is being programmed or erased causes DQ6 to toggle. When the operation is complete, DQ6 stops toggling.

After an erase command sequence is written, if all sectors selected for erasing are protected, DQ6 toggles for approximately 100µs, then returns to reading array data. If not all selected sectors are protected, the Embedded Erase algorithm erases the unprotected sectors, and ignores the selected sectors that are protected.

The system can use DQ6 and DQ2 together to determine whether a sector is actively erasing or is erase 2suspended. When the device is actively erasing (that is, the Embedded Erase algorithm is in progress), DQ6 toggles. When the device enters the Erase Suspend mode, DQ6 stops toggling. However, the system must also use DQ2 to determine which sectors are erasing or erase-suspended. Alternatively, the system can use DQ7.

If a program address falls within a protected sector, DQ6 toggles for approximately 1µs after the program command sequence is written, then returns to reading array data. DQ6 also toggles during the erase-suspend-program mode, and stops toggling once the Embedded Program Algorithm is complete. Toggle Bit I on DQ6 requires either OE# or CE# to be de-asserted and reasserted to show the change in state.

### DQ2: Toggle Bit II

The "Toggle Bit II" on DQ2, when used with DQ6, indicates whether a particular sector is actively erasing (that is, the Embedded Erase algorithm is in progress), or whether that sector is erase-suspended. Toggle Bit II is valid after the rising edge of the final WE# pulse in the command sequence. DQ2 toggles when the system reads at addresses within those sectors that have been selected for erasure. But DQ2 cannot distinguish whether the sector is actively erasing or is erase-suspended. DQ6, by comparison, indicates whether the device is actively erasing, or is in Erase Suspend, but cannot distinguish which sectors are selected for erasure. Thus, both status bits are required for sector and mode information.

#### Reading Toggle Bits DQ6/DQ2

Whenever the system initially begins reading toggle bit status, it must read DQ7–DQ0 at least twice in a row to determine whether a toggle bit is toggling. Typically, the system would note and store the value of the toggle bit after the first read. After the second read, the system would compare the new value of the toggle bit with the first. If the toggle bit is not toggling, the device has completed the program or erases operation. The system can read array data on DQ7-DQ0 on the following read cycle. However, if after the initial two read cycles, the system determines that the toggle bit is still toggling, the system also should note whether the value of DQ5 is high. If it is, the system should then determine again whether the toggle bit is toggling, since the toggle bit may have stopped toggling just as DQ5 went high. If the toggle bit is no longer toggling, the device has successfully completed the program or erases operation. If it is still toggling, the device did not complete the operation successfully, and the system must write the reset command to return to reading array data. The remaining scenario is that the system initially determines that the toggle bit is toggling and DQ5 has not gone high. The system may continue to monitor the toggle bit and DQ5 through successive read cycles, determining the status as described in the previous paragraph. Alternatively, it may choose to perform other system tasks. In this case, the system must start at the beginning of the algorithm when it returns to determine the status of the operation.

#### Note

When verifying the status of a write operation (embedded program/erase) of a memory sector, DQ6 and DQ2 toggle between high and low states in a series of consecutive and contiguous status read cycles. In order for this toggling behavior to be properly observed, the consecutive status bit reads must not be interleaved with read accesses to other memory sectors. If it is not possible to temporarily prevent reads to other memory sectors, then it is recommended to use the DQ7 status bit as the alternative method of determining the active or inactive status of the write operation.

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### **DQ5: Exceeded Timing Limits**

DQ5 indicates whether the program or erase time has exceeded a specified internal pulse count limit. Under these conditions DQ5 produces a "1," indicating that the program or erase cycle was not successfully completed. The device does not output a 1 on DQ5 if the system tries to program a 1 to a location that was previously programmed to 0. Only an erase operation can change a 0 back to a 1. Under this condition, the device ignores the bit that was incorrectly instructed to be programmed from a 0 to a 1, while any other bits that were correctly requested to be changed from 1 to 0 are programmed. Attempting to program a 0 to a 1 is masked during the programming operation. Under valid DQ5 conditions, the system must write the reset command to return to the read mode (or to the erase-suspend-read mode if a sector was previously in the erase-suspend-program mode).

### **DQ3: Sector Erase Timeout State Indicator**

After writing a sector erase command sequence, the output on DQ3 can be checked to determine whether or not an erase operation has begun. (The sector erase timer does not apply to the chip erase command.) When sector erase starts, DQ3 switches from "0" to "1". This device does not support multiple sector erase (continuous sector erase) command sequences so it is not very meaningful since it immediately shows as a "1" after the first 30h command. Future devices may support this feature.

#### DQ1: Write to Buffer Abort

DQ1 indicates whether a Write to Buffer operation was aborted. Under these conditions DQ1 produces a "1". The system must issue the "Write to Buffer Abort Reset" command sequence to return the device to reading array data.

	Stat	DQ7 (note 2)	DQ6	DQ5 (note 1)	DQ3	DQ2 (note 2)	DQ1	RY/BY#	
Standard	Embedde	ed Program Algorithm	DQ7#	Toggle	0	N/A	No Toggle	0	0
Mode	Embedded Erase Algorithm		0	Toggle	0	1	Toggle	N/A	0
Program Suspend	Program Suspended Suspend		Invalid (Not allowed)						
Mode	Read	Non-Program Suspended Sector			Data				1
	Erase	Erase Suspended Sector	1	No Toggle	0	N/A	Toggle	N/A	1
Erase Suspend Mode	Suspend Read	Non-Erase Suspended Sector			Data				0
WOUE	Erase Suspend Program (Embedded Program)		DQ7#	Toggle	0	N/A	N/A	N/A	0
Write to	Write to         Busy(note 3)           Buffer         Abort(note 4)		DQ7#	Toggle	0	N/A	N/A	0	0
Buffer			DQ7#	Toggle	0	N/A	N/A	1	0

#### Table 5. Write Operation Status

#### Notes

- 1. DQ5 switches to 1 when an Embedded Program, Embedded Erase, or Write-to-Buffer operation has exceeded the maximum timing limits.
- 2. DQ7 and DQ2 require a valid address when reading status information. Refer to the appropriate subsection for further details.
- 3. The Data# Polling algorithm should be used to monitor the last loaded write-buffer address location.
- 4. DQ1 switches to 1 when the device has aborted the write-to-buffer operation

### Writing Commands/Command Sequences

During a write operation, the system must drive CE# and WE# to VIL and OE# to VIH when providing an address, command, and data. Addresses are latched on the last falling edge of WE# or CE#, while data is latched on the 1st rising edge of WE# or CE#. An erase operation can erase one sector or the

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entire device. Table 3 indicate the address space that each sector occupies. The device address space is divided into uniform 32KW/64KB sectors. A sector address is the set of address bits required to uniquely select a sector. ICC2 in "DC Characteristics" represents the active current specification for the write mode. "AC Characteristics" contains timing specification tables and timing diagrams for write operations.

### RY/BY#

The RY/BY# is a dedicated, open-drain output pin that indicates whether an Embedded Algorithm is in progress or complete. The RY/BY# status is valid after the rising edge of the final WE# pulse in the command sequence. Since RY/BY# is an open-drain output, several RY/BY# pins can be tied together in parallel with a pull-up resistor to  $V_{CC}$ . This feature allows the host system to detect when data is ready to be read by simply monitoring the RY/BY# pin, which is a dedicated output and controlled by CE# (not OE#).

#### Hardware Reset

The RESET# input provides a hardware method of resetting the device to reading array data. When RESET# is driven low for at least a period of tRP (RESET# Pulse Width), the device immediately terminates any operation in progress, tristates all outputs, resets the configuration register, and ignores all read/write commands for the duration of the RESET# pulse. The device also resets the internal state machine to reading array data.

To ensure data integrity Program/Erase operations that were interrupted should be reinitiated once the device is ready to accept another command sequence.

When RESET# is held at VSS, the device draws  $V_{CC}$  reset current (ICC5). If RESET# is held at VIL, but not at VSS, the standby current is greater. RESET# may be tied to the system reset circuitry which enables the system to read the boot-up firmware from the Flash memory upon a system reset.

#### **Software Reset**

Software reset is part of the command set that also returns the device to array read mode and must be used for the following conditions:

- 1. To exit Autoselect mode
- 2. When DQ5 goes high during write status operation that indicates program or erase cycle was not successfully completed
- 3. Exit sector lock/unlock operation.
- 4. To return to erase-suspend-read mode if the device was previously in Erase Suspend mode.
- 5. After any aborted operations

The following are additional points to consider when using the reset command:

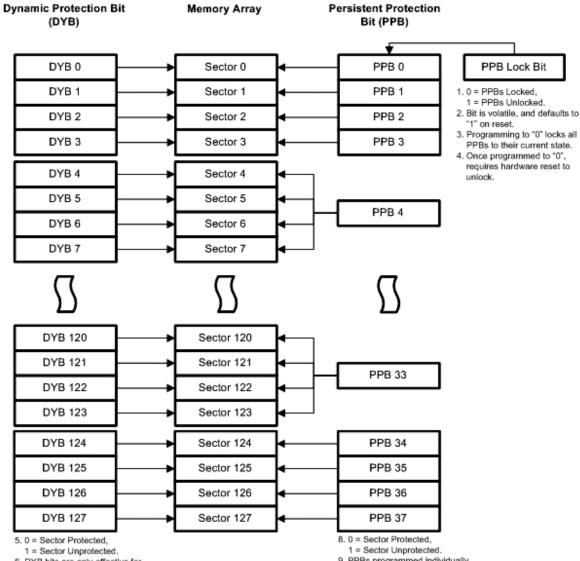
- This command resets the sectors to the read and address bits are ignored.
- Reset commands are ignored during program and erase operations.
- The reset command may be written between the cycles in a program command sequence before programming begins (prior to the third cycle). This resets the sector to which the system was writing to the read mode.
- If the program command sequence is written to a sector that is in the Erase Suspend mode, writing the reset command returns that sector to the erase-suspend-read mode.
- The reset command may be written during an Autoselect command sequence.
- If a sector has entered the Autoselect mode while in the Erase Suspend mode, writing the reset command returns that sector to the erase-suspend-read mode.
- If DQ1 goes high during a Write Buffer Programming operation, the system must write the "Write to Buffer Abort Reset" command sequence to RESET the device to reading array data. The standard RESET command does not work during this condition.

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#### **Advanced Sector Protection/Unprotection**

The Advanced Sector Protection/Unprotection feature disables or enables programming or erase operations in any or all sectors and can be implemented through software and/or hardware methods, which are independent of each other. This section describes the various methods of protecting data stored in the memory array. An overview of these methods in shown in Figure 8.



#### Figure 8a. Advanced Sector Protection/Unprotection for Uniform Sector

 DYB bits are only effective for sectors that not protected via

PPB locking mechanism. 7. Volatile Bits: defaults to

unprotected after power up.

 9. PPBs programmed individually, but cleared collectively.
 10.Sector 0~3 and 124~127 have

PPB for each sector. Sector 4~123 are 1 PPB per 4 sectors.

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#### DYB 0 Sector 0 PPB Lock Bit DYB 1 Sector 1 1.0 = PPBs Locked. PPB 0 2. Bit is volatile, and defaults to DYB 2 Sector 2 "1" on reset. DYB 3 Sector 3 PPBs to their current state. unlock. DYB 120 Sector 120 DYB 121 Sector 121 PPB 30 DYB 122 Sector 122 DYB 123 Sector 123 DYB 124 Sector 124 PPB 31 DYB 125 Sector 125 **PPB 32** DYB 126 Sector 126 PPB 33 DYB 127 PPB 34 Sector 127 **PPB 35** DYB 128 Sector 128 DYB 129 **PPB 36** Sector 129 DYB 130 PPB 37 Sector 130 DYB 131 Sector 131 **PPB 38** DYB 132 Sector 132 **PPB 39**

Figure 8b. Advanced Sector Protection/Unprotection for Top Boot Sector

Memory Array

**Dynamic Protection Bit** (DYB)

Persistent Protection Bit (PPB)

1 = PPBs Unlocked.

3. Programming to "0" locks all

4. Once programmed to "0", requires hardware reset to

DYB 134 5. 0 = Sector Protected.

DYB 133

1 = Sector Unprotected. 6. DYB bits are only effective for sectors that not protected via

PPB locking mechanism.

7. Volatile Bits: defaults to

unprotected after power up.

0 = Sector Protected. 1 = Sector Unprotected.

PPB 40

PPB 41

9. PPBs programmed individually,

but cleared collectively.

10.Sector 0~123 are 1 PPB per 4 sectors and Sector 124-134 have PPB for each boot sector.

Sector 133

Sector 134

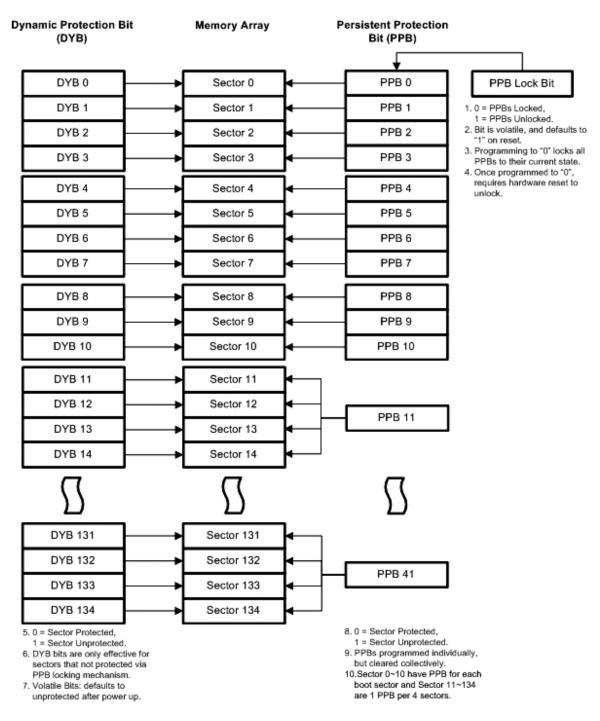


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#### Figure 8c. Advanced Sector Protection/Unprotection for Bottom Boot Sector



#### Lock Register

The Lock Register consists of 4 bits. The Secured Silicon Sector Protection Bit is DQ0, Persistent Protection Mode Lock Bit is DQ1, Persistent Sector Protection OTP bit is DQ3 and DYB Lock Boot Bit is DQ4. If DQ0 is '0', it means that the Customer Secured Silicon area is locked and if DQ0 is '1', it means that it is unlocked. When DQ1 is set to '0', the device is used in the Persistent Protection Mode. DQ3 is programmed in the EON factory. When the device is programmed to disable all PPB erase command, DQ3 outputs a '0', when the lock register bits are read. Similarly, if the device is programmed to enable all PPB erase command, DQ3 outputs a '1' when the lock register bits are read. Likewise the DQ4 bit is

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also programmed in the EON Factory. DQ4 is the bit which indicates whether Volatile Sector Protection Bit (DYB) is protected or not after boot-up. When the device is programmed to set all Volatile Sector Protection Bit protected after power-up, DQ4 outputs a '0' when the lock register bits are read. Similarly, when the device is programmed to set all Volatile Sector Protection Bit unprotected after power-up, DQ4 outputs a '1'. Each of these bits in the lock register are non-volatile. DQ15- DQ5 are reserved and will be 1's.

#### Table 6. Lock Register

DQ15-5	DQ4	DQ3	DQ2	DQ1	DQ0
Reserved	DYB Lock Boot Bit	PPB One Time Programmable Bit	Reserved	Persistent Protection Mode Lock Bit	Secured Silicon Sector Protection Bit
(default = 1)	1 = unprotected all DYB after boot-up	Command disabled 1 = All PPB Erase		0 = Persistent Protection enabled (default = 0)	0 = protected 1 = unprotect (default = 1)

Notes:

1. After the Lock Register Bits Command Set Entry command sequence is written, reads and writes for all Sector are disabled, while reads from other sectors are allowed until exiting this mode.

2. Only DQ0 could be change by Lock Register Bits Command for user. Others bits were set by Factory.

3. If user needs the product of DQ3 = 0, please chose the EN29GA064AT/B. For the detail information of EN29GA064AT/B please contact with Eon directly.

After selecting a sector protection method, each sector can operate in any of the following three states:

- 1. Constantly locked: The selected sectors are protected and can not be reprogrammed unless PPB
- lock bit is cleared via hardware reset, or power cycle.

2. Dynamically locked: The selected sectors are protected and can be altered via software commands.

3. Unlocked: The sectors are unprotected and can be erased and/or programmed.

### **Persistent Protection Bits**

The Persistent Protection Bits are unique and nonvolatile. For uniform sector device, Sector 0~3 and 124~127 have one PPB for each sectors and for Sector 4~123 have one PPB every four sectors. For top boot sector device, Sector 0~123 are 1 PPB per 4 sectors and Sector 124~134 have PPB for each boot sector. For bottom boot sector device, Sector 0~10 have PPB for each boot sector and Sector 11~134 are 1 PPB per 4 sectors(refer to Figure 8a, 8b, 8c and Table 3a, 3b, 3c). The PPB has the same endurances as the Flash memory. Preprogramming and verification prior to erasure are handled by the device, and therefore do not require system monitoring.

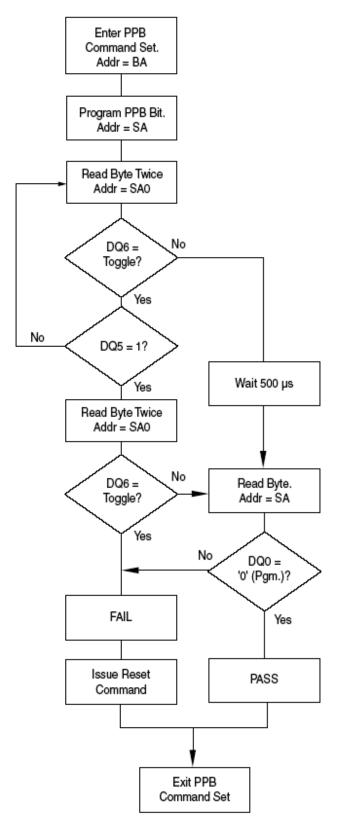
#### Notes

- 1. Each PPB is individually programmed and all are erased in parallel.
- 2. While programming PPB for the four sectors and Data polling on programming PPB address, array data can not be read from any sectors.
- 3. Entry command disables reads and writes for all sectors selected.
- 4. Reads within that sector return the PPB status for that sector.
- 5. All Reads must be performed using the read mode.
- 6. The specific sector address are written at the same time as the program command.
- 7. If the PPB Lock Bit is set, the PPB Program or erase command does not execute and times-out without programming or erasing the PPB.
- 8. There are no means for individually erasing a specific PPB and no specific sector address is required for this operation.
- Exit command must be issued after the execution which resets the device to read mode and reenables reads and writes for all sectors.
- 10. The programming state of the PPB for given sectors can be verified by writing a PPB Status Read Command to the device as described by the flow chart shown in Figure 9. User only can use DQ6 and RY/BY# pin to detect programming status.

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### Figure 9. PPB Program Algorithm



Note: BA = base address

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### **Dynamic Protection Bits**

Dynamic Protection Bits are volatile and unique for each sector and can be individually modified. DYBs only control the protection scheme for unprotected sectors that have their PPBs cleared (erased to "1"). By issuing the DYB Set or Clear command sequences, the DYBs are set (programmed to "0") or cleared (erased to "1"), thus placing each sector in the protected or unprotected state respectively. This feature allows software to easily protect sectors against inadvertent changes yet does not prevent the easy removal of protection when changes are needed.

#### Notes

1. The DYBs can be set (programmed to "0") or cleared (erased to "1") as often as needed. When the parts are first shipped, the PPBs are cleared (erased to "1") and upon power up or reset, the DYBs can be set or cleared depending upon the ordering option chosen.

2. If the option to clear the DYBs after power up is chosen, (erased to "1"), then the sectorsmay be modified depending upon the PPB state of that sector (see Table 7).

3. The sectors would be in the protected state If the option to set the DYBs after power up is chosen (programmed to "0").

4. It is possible to have sectors that are persistently locked with sectors that are left in the dynamic state.

5. The DYB Set or Clear commands for the dynamic sectors signify protected or unprotectedstate of the sectors respectively. However, if there is a need to change the status of the persistently locked sectors, a few more steps are required. First, the PPB Lock Bit must be cleared by either putting the device through a power-cycle, or hardware reset. The PPBs can then be changed to reflect the desired settings. Setting the PPB Lock Bit once again locks the PPBs, and the device operates normally again.

6. To achieve the best protection, it is recommended to execute the PPB Lock Bit Set command early in the boot code and protect the boot code by holding WP#/ACC = VIL. Note that the PPB and DYB bits have the same function when WP#/ACC = VHH as they do when ACC =VIH.

#### **Persistent Protection Bit Lock Bit**

The Persistent Protection Bit Lock Bit is a global volatile bit for all sectors. When set (programmed to "0"), it locks all PPBs and when cleared (erased to "1"), allows the PPBs to be changed. There is only one PPB Lock Bit per device.

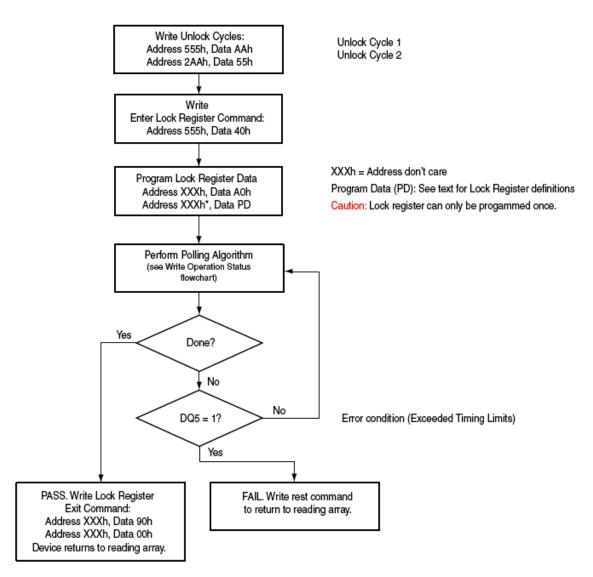
#### Notes

- 1. No software command sequence unlocks this bit, but only a hardware reset or a power-up clears this bit.
- 2. The PPB Lock Bit must be set (programmed to "0") only after all PPBs are configured to the desired settings.





#### Figure 10. Lock Register Program Algorithm



### **Advanced Sector Protection Software Examples**

#### Table 7. Sector Protection Schemes: DYB, PPB and PPB Lock Bit Combinations

Unique Device PPB Loc 0 = locked 1 = unlocked	k Bit	Sector PPB 0 = protected 1 = unprotected	Sector DYB 0 = protected 1 = unprotected	Sector Protection Status
Any Sector	0	0	х	Protected through PPB
Any Sector	0	0	x	Protected through PPB
Any Sector	0	1	1	Unprotected
Any Sector	0	1	0	Protected through DYB
Any Sector	1	0	х	Protected through PPB
Any Sector	1	0	x	Protected through PPB
Any Sector	1	1	0	Protected through DYB
Any Sector	1	1	1	Unprotected

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Table 7 contains all possible combinations of the DYB, PPB, and PPB Lock Bit relating to the status of the sector. In summary, if the PPB Lock Bit is locked (set to "0"), no changes to the PPBs are allowed. The PPB Lock Bit can only be unlocked (reset to "1") through a hardware reset or power cycle. See also Figure 9 for an overview of the Advanced Sector Protection feature.

#### Hardware Data Protection Methods

The device offers two main types of data protection at the sector level via hardware control:

 When WP#/ACC is at VIL, the either the highest or lowest sector is locked (device specific). There are additional methods by which intended or accidental erasure of any sectors can be prevented via hardware means. The following subsections describes these methods:

#### **WP#/ACC Method**

The Write Protect feature provides a hardware method of protecting one outermost sector. This function is provided by the WP#/ACC pin and overrides the previously discussed Sector Protection/Unprotection method.

If the system asserts VIL on the WP#/ACC pin, the device disables program and erase functions in the highest or lowest sector independently of whether the sector was protected or unprotected using the method described in Advanced Sector Protection/Unprotection.

If the system asserts VIH on the WP#/ACC pin, the device reverts to whether the boot sectors were last set to be protected or unprotected. That is, sector protection or unprotection for these sectors depends on whether they were last protected or unprotected.

The WP#/ACC pin must be held stable during a command sequence execution. WP# has an internal pull-up; when unconnected, WP# is set at VIH.

#### Note

If WP#/ACC is at VIL when the device is in the standby mode, the maximum input load current is increased.

#### Low V<sub>CC</sub> Write Inhibit

When VCC is less than VLKO, the device does not accept any write cycles. This protects data during VCC power-up and power-down.

The command register and all internal program/erase circuits are disabled, and the device resets to reading array data. Subsequent writes are ignored until VCC is greater than VLKO. The system must provide the proper signals to the control inputs to prevent unintentional writes when VCC is greater than VLKO.

#### Write Pulse "Glitch Protection"

Noise pulses of less than 5 ns (typical) on OE#, CE# or WE# do not initiate a write cycle.

#### **Power-Up Write Inhibit**

If WE# = CE# = RESET# = VIL and OE# = VIH during power up, the device does not accept commands on the rising edge of WE#. The internal state machine is automatically reset to the read mode on power-up.

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### **Power Conservation Modes**

#### Standby Mode

When the system is not reading or writing to the device, it can place the device in the standby mode. In this mode, current consumption is greatly reduced, and the outputs are placed in the high impedance state, independent of the OE# input. The device enters the CMOS standby mode when the CE# and RESET# inputs are both held at  $V_{CC} \pm 0.3$  V. The device requires standard access time (tCE) for read access, before it is ready to read data. If the device is deselected during erasure or programming, the device draws active current until the operation is completed. ICC4 in "DC Characteristics" represents the standby current specification

#### **Automatic Sleep Mode**

The automatic sleep mode minimizes Flash device energy consumption. The device automatically enables this mode when addresses remain stable for tACC + 30 ns. The automatic sleep mode is independent of the CE#, WE#, and OE# control signals. Standard address access timings provide new data when addresses are changed. While in sleep mode, output data is latched and always available to the system.

#### Hardware RESET# Input Operation

The RESET# input provides a hardware method of resetting the device to reading array data. When RESET# is driven low for at least a period of tRP, the device immediately terminates any operation in progress, tristates all outputs, and ignores all read/write commands for the duration of the RESET# pulse. The device also resets the internal state machine to reading array data. The operation that was interrupted should be reinitiated once the device is ready to accept another command sequence to ensure data integrity.

When RESET# is held at VSS  $\pm$  0.3 V, the device draws ICC reset current (ICC5). If RESET# is held at VIL but not within VSS  $\pm$  0.3 V, the standby current is greater.

RESET# may be tied to the system reset circuitry and thus, a system reset would also reset the Flash memory, enabling the system to read the boot-up firmware from the Flash memory.

#### Output Disable (OE#)

When the OE# input is at VIH, output from the device is disabled. The outputs are placed in the high impedance state. (With the exception of RY/BY#.)

#### Secured Silicon Sector Flash Memory Region

The Secured Silicon Sector provides an extra Flash memory region. The Secured Silicon Sector is 128 words in length and all Secured Silicon reads outside of the 128-word address range returns invalid data. The Secured Silicon Sector Indicator Bit, DQ7, (at Autoselect address 03h) is used to indicate whether or not the Secured Silicon Sector is locked when shipped from the factory.

Please note the following general conditions:

- On power-up, or following a hardware reset, the device reverts to sending commands to the normal address space.
- Reads outside of sector SA0 return memory array data.
- Sector SA0 is remapped from memory array to Secured Silicon Sector array.
- Once the Secured Silicon Sector Entry Command is issued, the Secured Silicon Sector Exit command must be issued to exit Secured Silicon Sector Mode.
- The Secured Silicon Sector is not accessible when the device is executing an Embedded Program or Embedded Erase algorithm.
- When sector SA0 is suspended, if system enters Secured Silicon Sector mode, the Secured Silicon Sector Region cannot be read. If the system suspends the flash in other sectors except SA0, Secured Silicon Sector Region can be read normally.
- The ACC function is not available when the Secured Silicon Sector is enabled.

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#### **Table 8. Secured Silicon Sector Addresses**

Secured Silicon Sector Address Range							
000000h-000007h	Reserve for Factory						
000008h-00007Fh	Determined by customer						

#### **Customer Lockable Secured Silicon Sector**

The Customer Lockable Secured Silicon Sector is always shipped unprotected (DQ0 set to "1"), allowing

customers to utilize that sector in any manner they choose. If the security feature is not required, the Secured Silicon Sector can be treated as an additional Flash memory space.

Please note the following:

- Once the Secured Silicon Sector area is protected, the Secured Silicon Sector Indicator Bit (DQ0) is permanently set to "0."
- The Secured Silicon Sector can be read any number of times, but can be programmed and locked only once. The Secured Silicon Sector lock must be used with caution as once locked, there is no procedure available for unlocking the Secured Silicon Sector area and none of the bits in the Secured Silicon Sector memory space can be modified in any way.
- The accelerated programming (ACC) is not available when the Secured Silicon Sector is enabled.
- Once the Secured Silicon Sector is locked and verified, the system must write the Exit Secured Silicon Sector Region command sequence which return the device to the memory array at sector 0.
- The address 0h~7h in Secured Silicon Sector is reserved for Factory.

#### Secured Silicon Sector Entry/Exit Command Sequences

The system can access the Secured Silicon Sector region by issuing the three-cycle Enter Secured Silicon Sector command sequence. The device continues to access the Secured Silicon Sector region until the system issues the four-cycle Exit Secured Silicon Sector command sequence.

The Secured Silicon Sector Entry Command allows the following commands to be executed

- Read customer and factory Secured Silicon areas
- Program the customer Secured Silicon Sector

After the system has written the Enter Secured Silicon Sector command sequence, it may read the Secured Silicon Sector by using the addresses normally occupied by sector SA0 within the memory array. This mode of operation continues until the system issues the Exit Secured Silicon Sector command sequence, or until power is removed from the device.

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#### COMMON FLASH INTERFACE (CFI)

The common flash interface (CFI) specification outlines device and host systems software interrogation handshake, which allows specific vendor-specified software algorithms to be used for entire families of devices. Software support can then be device-independent, JEDEC ID-independent, and forward- and backward-compatible for the specified flash device families. Flash vendors can standardize their existing interfaces for long-term compatibility.

This device enters the CFI Query mode when the system writes the CFI Query command, 98h, to address 55h in word mode (or address AAh in byte mode), any time the device is ready to read array data.

The system can read CFI information at the addresses given in Tables 9~11.In word mode, the upper address bits (A7–MSB) must be all zeros. To terminate reading CFI data, the system must write the reset command.

The system can also write the CFI query command when the device is in the autoselect mode. The device enters the CFI query mode and the system can read CFI data at the addresses given in Tables 9~11. The system must write the reset command to return the device to the autoselect mode.

Addresses (Word Mode)	Data	Description
10h	0051h	
11h	0052h	Query Unique ASCII string "QRY"
12h	0059h	
13h	0002h	Drimony OEM Command Sat
14h	0000h	Primary OEM Command Set
15h	0040h	Address for Drimony Extended Table
16h	0000h	Address for Primary Extended Table
17h	0000h	Alternate OEM Command act (00h - none aviate)
18h	0000h	Alternate OEM Command set (00h = none exists)
19h	0000h	Address for Alternate OEM Extended Table (00b - pape existe)
1Ah	0000h	Address for Alternate OEM Extended Table (00h = none exists)

#### Table 9. CFI Query Identification String

#### Table 10. System Interface String

Addresses (Word Mode)	Data	Description
1Bh	0027h	Vcc Min (write/erase) DQ7-DQ4: volt, DQ3-DQ0: 100mV
1Ch	0036h	Vcc Max (write/erase) DQ7-DQ4: volt, DQ3-DQ0: 100mV
1Dh	0000h	Vpp Min voltage (00h = no Vpp pin present)
1Eh	0000h	Vpp Max voltage (00h = no Vpp pin present)
1Fh	0003h	Typical timeout per single byte/word write 2 <sup>N</sup> µs
20h	0004h	Typical timeout for min size buffer write $2^{N} \mu s$ (00h = not supported)
21h	0009h	Typical timeout per individual block erase 2 <sup>N</sup> ms
22h	0000h	Typical timeout for full chip erase 2 <sup>N</sup> ms (00h = not supported)
23h	0005h	Max timeout for byte/word write 2 <sup>N</sup> times typical
24h	0005h	Max timeout for buffer write 2 <sup>N</sup> times typical
25h	0004h	Max timeout per individual block erase 2 <sup>N</sup> times typical
26h	0000h	Max timeout for full chip erase 2 <sup>N</sup> times typical (00h = not supported)

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Addresses		
(Word mode)	Data	Description
27h	0017h	Device Size = 2 <sup>N</sup> bytes. 2**23=8MB=64Mb
28h	0002h	Flash Device Interface Description (refer to CFI publication 100);
29h	0000h	01h = X16 only; 02h = x8/x16
2Ah	0005h	Max number of byte in multi-byte write = 2 <sup>N</sup>
2Bh	0000h	(00h = not supported)
2Ch	00xxh	Number of Erase Block Regions within device (01h = uniform device, 02h = boot device)
2Dh	00xxh	Erase Block Region 1 Information
2Eh	0000h	(refer to the CFI specification of CFI publication 100)
2Fh	00x0h	EN29GL064 H and L : 007Fh, 0000h, 0000h, 0001h
30h	000xh	EN29GL064 B and T : 0007h, 0000h, 0020h, 0000h
31h	00xxh	Erase Block Region 2 Information
32h	0000h	(refer to the CFI specification of CFI publication 100)
33h	0000h	EN29GL064 H and L : 0000h, 0000h, 0000h, 0000h
34h	000xh	EN29GL064 B and T : 007Eh, 0000h, 0000h, 0001h
35h	0000h	
36h	0000h	Erase Block Region 3 Information
37h	0000h	(refer to the CFI specification of CFI publication 100)
38h	0000h	
39h	0000h	
3Ah	0000h	Erase Block Region 4 Information
3Bh	0000h	(refer to the CFI specification of CFI publication 100)
3Ch	0000h	

#### Table 11. Device Geometry Definition

### Table 12. Primary Vendor-specific Extended Query

Addresses (Word Mode)	Data	Description
40h	0050h	
41h	0052h	Query Unique ASCII string "PRI"
42h	0049h	
43h	0031h	Major version number, ASCII
44h	0034h	Minor version number, ASCII
45h	000Ch	Address Sensitive Unlock (Bits 1-0) 00 = Required, 01 = Not Required Technology (Bits 5-2) 0001 = 0.18um, 0010 = 0.13um, 0011 = 90nm
46h	0002h	Erase Suspend 0 = Not Supported, 1 = To Read Only, 2 = To Read & Write
47h	0001h	Sector Protect 0 = Not Supported, X = Minimum number of sectors per group
48h	0000h	Sector Temporary Unprotect 00 = Not Supported, 01 = Supported
49h	0003h	Sector Protect/Unprotect Scheme 00h = High Voltage Sector Protection 01h = High Voltage + In-System Sector Protection 02h = HV + In-System + Software Command Sector Protection 03h = Software Command Sector Protection
4Ah	0000h	Simultaneous Operation 00 = Not supported, X = Number of Sectors
4Bh	0000h	Burst Mode Type 00 = Not Supported, 01 = Supported

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4Ch	0002h	Page Mode Type 00 = Not Supported, 01 = 4 Word Page, 02 = 8 Word Page
4Dh	0085h	Minimum WP#/ACC (Acceleration) Supply Voltage 00 = Not Supported, DQ7-DQ4: Volts, DQ3=DQ0: 100mV
4Eh	0095h	Maximum WP#/ACC (Acceleration) Supply Voltage 00 = Not Supported, DQ7-DQ4: Volts, DQ3=DQ0: 100mV
4Fh	000xh	Top/Bottom Boot Sector Flag 02 = Bottom Boot Device, 03 = Top Boot Device 04 = Uniform sectors bottom WP# protect 05 = Uniform sectors top WP# protect
50h	0001h	Program Suspend 00 = Not Supported, 01 = Supported
52h	0008h	Secured Silicon Sector (Customer OTP Area) Size 2 <sup>N</sup> bytes
53h	000Fh	Hardware Reset Low Time-out during an embedded algorithm to read mode Maximum 2 <sup>N</sup> ns
54h	0009h	Hardware Reset Low Time-out not during an embedded algorithm to read mode Maximum $2^{N}$ ns
55h	0005h	Erase Suspend Latency Maximum 2 <sup>N</sup> µs
56h	0005h	Program Suspend Latency Maximum 2 <sup>N</sup> µs
57h	0000h	Bank Organization 00 = Data at 4Ah is zero, X = Number of Banks

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#### Table 13. EN29GL064 Command Definitions

					Bus Cycles												
	Command Sequence		Cycles	1 <sup>st</sup> Cycle		2 <sup>,nd</sup> , (	Cycle	3. <sup>rd</sup> . (	Cycle	4, <sup>th</sup> .	Cycle	5. <sup>th</sup> .	Cycle	6. <sup>th</sup> . (	cycle		
	•		0	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data		
Rea	ad		1	RA	RD												
Res	set		1	XXX	F0												
	Manufacturer	Word	4	555	AA	2AA		555	90	000 100	7F 1C						
	ID	Byte	4	AAA	AA	555	- 55	AAA	90	000 200	7F 1C						
t	Device ID Uniform	Word Byte	4	555 AAA	AA	2AA 555	55	555 AAA	90	X01 X02	227E 7E	X0E X1C	220C 0C	X0F X1E	2201 01		
Autoselect	Device ID Top Boot	Word Byte	4	555 AAA	AA	2AA 555	55	555 AAA	90	X01 X02	227E 7E	X0E X1C	2210 10	X0F X1E	2201 01		
Aut	Device ID	Word		555		2AA		555		X01	227E	X0E	2210	X0F	2200		
	Bottom Boot	Byte	4	AAA AA	555	55	AAA	90	X02	7E	X1C	10	X1E	00			
	Sector Protect	Word	4	555 AA	2AA	55	555	90	(SA) X02	00 01							
	Verify	Byte	4	AAA	- AA	555	55	55 AAA	90	(SA) X04	00 01						
Dro	gram	Word	4	555	AA	2AA	55	555	A0	PA	PD						
FIU	gram	Byte	4	AAA		555	55	AAA	70	FA	FD						
\//ri	te to Buffer	Word	6	555	AA	2AA	55	SA	25	SA	WC	PA	PD	WBL	PD		
VVII		Byte	0	AAA		555	- 55	57	25	0/( //	~~~	17	10	WBL	TD		
Pro	gram Buffer to	Word	1	PA	29												
Fla	sh	Byte			23												
Wri	te to Buffer	Word	3	555	AA	2AA	- 55	555	F0								
Abo	ort Reset	Byte	3	AAA	AA	555	55	555									
Chi	p Erase	Word	6	555	AA	2AA	55	555	80	555	AA	2AA	55	555	10		
CIII	p Elase	Byte	0	AAA	AA	555	55	AAA	00	AAA	AA	555	55	AAA	10		
Ser	tor Erase	Word	6	555	AA	2AA	55	555	80	555	AA	2AA	55	SA	30		
000		Byte		AAA	· · ·	555		AAA	00	AAA		555					
Erase/Program Suspend		1	XXX	B0													
Erase/Program Resume		1	XXX	30													
Secured Silicon Sector Entry		3	555	AA	2AA	55	555	88									
Secured Silicon Sector Exit		4	555	AA	2AA	55	555	90	XX	00							
CFI	Query	Word Byte	1	55 AA	98												
Acc	elerated Program	10,10	2	XX	A0	PA	PD										

#### Legend

X = Don't care

RA = Address of the memory to be read.

RD = Data read from location RA during read operation.

PA = Address of the memory location to be programmed. Addresses latch on the falling edge of the WE# or CE# pulse,

whichever happens later.

PD = Data to be programmed at location PA. Data latches on the rising edge of the WE# or CE# pulse, whichever happens first. SA = Address of the sector to be verified (in autoselect mode) or erased. Address bits Amax–A16 uniquely select any sector.

WBL = Write Buffer Location. The address must be within the same write buffer page as PA.

WC = Word Count is the number of write buffer locations to load minus 1 and maximum value is 31 for word and byte mode.

#### Note:

The data is 00h for an unprotected sector and 01h for a protected sector. This is same as PPB Status Read except that the protect and unprotect statuses are inverted here

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#### Table 14. EN29GL064 Command Definitions

									Bus (	Cycles					
	Command Sequence		Cycles	1. <sup>st</sup> . (	Cycle	2 <sup>nd</sup> Cycle		3 <sup>rd</sup> Cycle		4 <sup>th</sup> Cycle		5 <sup>,th</sup> Cycle		6 <sup>,th</sup> , 0	Cycle
			с С	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data
<u> </u>	Command Set	Word	3	555	AA	2AA	55	555	40						
Lock Register	Entry	Byte	3	AAA	AA	55	55	AAA	40						
Reć	Program		2	XXX	A0	XXX	Data								
ock	Read		1	00	RD										
	Command Set Ex	it	2	XXX	90	XXX	00								
	PPB Command	Word	3	555	AA	2AA	55	555	C0						
le	Set Entry	Byte	3	AAA	AA	55	55	AAA	C0						
Global Non-Volatile	PPB Program		2	XXX	A0	SA	00								
Global on-Volat	All PPB Erase		2	XXX	80	00	30								
ž	PPB Status Read	PPB Status Read		SA	RD										
	PPB Command S	et Exit	2	XXX	90	XXX	00								
	PPB Lock	Word	3	555	AA	2AA	55	555	50						
Global latile Freeze	Command Set Entry	Byte	3	AAA	AA	555	55	AAA	50						
Global ttile Fre	PPB Lock Set	I.	2	XXX	A0	XXX	00								
latile	PPB Lock Status	Read	1	XXX	RD										
Vol	PPB Lock Comma Exit	and Set	2	XXX	90	XXX	00								
	DYB Command	Word	3	555	AA	2AA	55	555	E0						
	Set Entry	Byte	3	AAA	AA	555	55	AAA	E0						
Volatile			2	XXX	A0	SA	00								
Vol	DYB Clear		2	XXX	A0	SA	01								
	DYB Status Read		1	SA	RD										
	DYB Command S	et Exit	2	XXX	90	XXX	00								

#### Legend

X = Don't care

RD(0) = Read data.

SA = Sector Address. Address bits Amax-A16 uniquely select any sector.

PWD = Password

PWDx = Password word0, word1, word2, and word3. Data = Lock Register Contents: PD(0) = Secured Silicon Sector Protection Bit, PD(1) = Persistent Protection Mode Lock Bit, PD(2) = Password Protection Mode Lock Bit.

#### Note:

Protected State = "00h," Unprotected State = "01h."

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#### Table 15. DC Characteristics

 $(T_a = -40^{\circ}C \text{ to } 85^{\circ}C; V_{CC} = 2.7-3.6V)$ 

Symbol	Parameter	Test Condition	S	Min	Тур	Max	Unit
ILI	Input Leakage Current	$0V \le V_{IN} \le Vcc$			±5	μA	
ILO	Output Leakage Current	$0V \le V_{OUT} \le Vcc$	C			±1	μA
laar	V <sub>CC</sub> Active Read Current	CE# = V <sub>IL</sub> ; OE# = V <sub>IH ;</sub>	5MHz		15	30	mA
I <sub>CC1</sub>		$V_{CC} = V_{CC} \max$	10MHz		25	45	mA
I <sub>CC2</sub>	V <sub>cc</sub> Intra-Page Read	$\begin{array}{l} CE\#=V_{IL,OE\#=V_{IH},V}\\ V_{CCmax,f=10MHz} \end{array}$		-	1	10	mA
1002	Current	$CE\# = V_{IL}, OE\# = V_{IH}, V$ $V_{CC}max, f = 33 MHz$	<sub>cc</sub> =		5	15	117.
I <sub>CC3</sub>	V <sub>CC</sub> Active Erase/ Program Current	$CE\# = V_{IL}$ , $OE\# = V_{IH}$ , $V_{CC}$			20	40	mA
I <sub>CC4</sub>	V <sub>CC</sub> Standby Current	CE#, RESET# = VCC $\pm$ 0.3 OE# = V <sub>IH</sub> , V <sub>CC</sub> = V <sub>CC</sub> ma V <sub>IL</sub> = Vss + 0.3 V/-0.1V,		2.0	20	μA	
I <sub>CC5</sub>	V <sub>CC</sub> Reset Current	RESET# = Vss ± 0.3V		2.0	20	μA	
I <sub>CC6</sub>	Automatic Sleep Mode	$V_{IH} = Vcc \pm 0.3V$ $V_{IL} = Vss \pm 0.3V$			2.0	20	μA
	ACC Accelerated Program	CE# = VIL, OE# = VIH, VCC = VCCmax.	WP#/ACC pin		3	10	mA
IACC	Current	WP#/ACC = VHH	Vcc pin		15	30	IIIA
VIL	Input Low Voltage			-0.5		0.3 x V <sub>CC</sub>	V
VIH	Input High Voltage			0.7 x V <sub>CC</sub>		VCC + 0.3	V
V <sub>HH</sub>	Acceleration Program Voltage			8.5		9.5	V
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 100μA			0.15 x V <sub>CC</sub>	V	
V <sub>OH</sub>	Output High Voltage CMOS	Ι <sub>ΟΗ</sub> = -100μΑ	0.85 x V <sub>CC</sub>			V	
V <sub>LKO</sub>	Supply voltage (Erase and Program lock-out)			2.3		2.5	V

Notes:

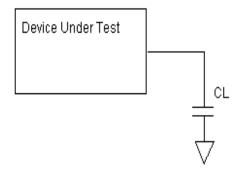
1. BYTE# pin can also be GND ± 0.3V. BYTE# and RESET# pin input buffers are always enabled so that they draw power if not at full CMOS supply voltages. 2. Maximum  $I_{cc}$  specifications are tested with Vcc = Vcc max. 3. Not 100% tested.

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### **Figure 11. Test Conditions**



#### Table 16. Test Specifications

Test Conditions	-70	Unit
Output Load Capacitance, $C_L$	30	pF
Input Rise and Fall times	5	ns
Input Pulse Levels	0.0- V <sub>CC</sub>	V
Input timing measurement reference levels	$0.5 V_{CC}$	V
Output timing measurement reference levels	$0.5 V_{CC}$	V

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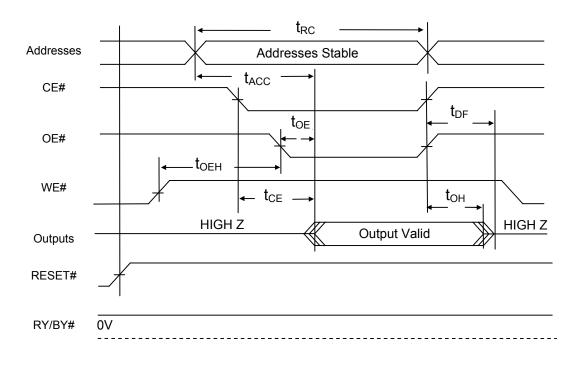


	ameter mbols	Descr	iption	Test Set	up	Speed	Unit	
JEDEC	Standard		<b>P</b>		•	-70	•	
t <sub>AVAV</sub>	t <sub>RC</sub>	Read Cycle Time			Min	70	ns	
t <sub>AVQV</sub>	t <sub>ACC</sub>	Address to Outp	CE# = V <sub>IL</sub> OE#= V <sub>IL</sub>	Max	70	ns		
$\mathbf{t}_{ELQV}$	t <sub>CE</sub>	Chip Enable To	Chip Enable To Output Delay			70	ns	
	t <sub>PACC</sub>	Page Access Ti		Max	25	ns		
t <sub>GLQV</sub>	t <sub>OE</sub>	Output Enable to	Output Enable to Output Delay			25	ns	
t <sub>EHQZ</sub>	t <sub>DF</sub>	Chip Enable to C	Dutput High Z		Max	20	ns	
t <sub>GHQZ</sub>	t <sub>DF</sub>	Output Enable to	o Output High Z		Max	20	ns	
t <sub>AXQX</sub>	t <sub>он</sub>	Output Hold Tim Addresses, CE# whichever occur	<sup>t</sup> or OE#,		Min	0	ns	
		Output Enable	Read		Min	0	ns	
	t <sub>OEH</sub>	Hold Time	Toggle and DATA# Polling		Min	10	ns	

#### **Table 17. Read-only Operations Characteristics**

Notes: High Z is Not 100% tested.

### Figure 12. AC Waveforms for READ Operations

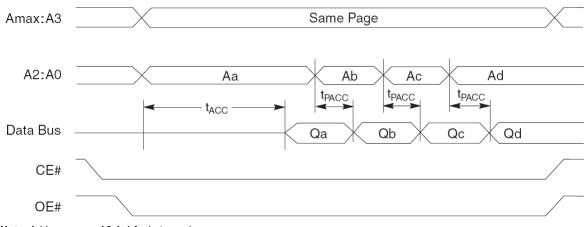


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#### Figure 13. Page Read Operation Timings



Note: Addresses are A2:A-1 for byte mode.

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#### Table 18. Hardware Reset (RESET#)

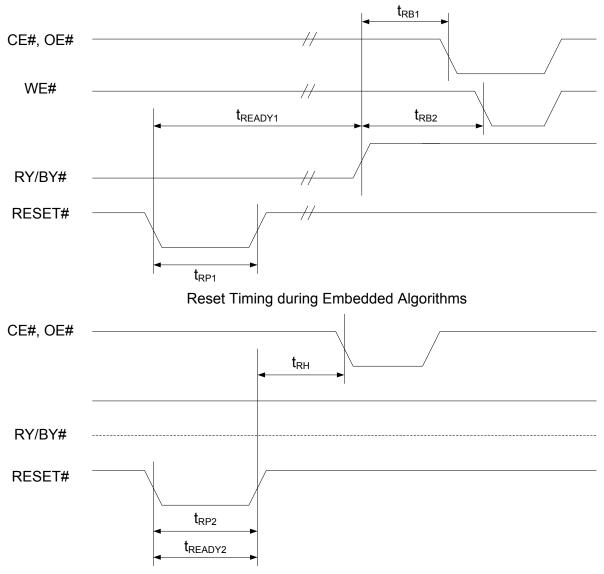
Paramete	Description	Test	Speed	Unit
r Std	Description	Setup	-70	Unit
t <sub>RP1</sub>	RESET# Pulse Width (During Embedded Algorithms)	Min	10	us
t <sub>RP2</sub>	RESET# Pulse Width (NOT During Embedded Algorithms)	Min	500	ns
t <sub>RH</sub>	Reset# High Time Before Read	Min	50	ns
t <sub>RB1</sub>	RY/BY# Recovery Time ( to CE#, OE# go low)	Min	0	ns
t <sub>RB2</sub>	RY/BY# Recovery Time ( to WE# go low)	Min	50	ns
t <sub>READY1</sub>	Reset# Pin Low (During Embedded Algorithms) to Read or Write	Max	20	us
t <sub>READY2</sub>	Reset# Pin Low (NOT During Embedded Algorithms) to Read or Write	Max	500	ns

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Figure 14. AC Waveforms for RESET# Reset# Timings



Reset Timing NOT during Embedded Algorithms

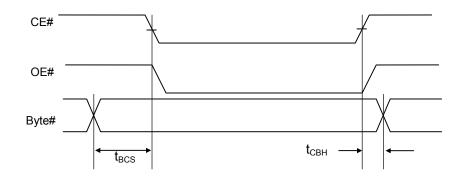
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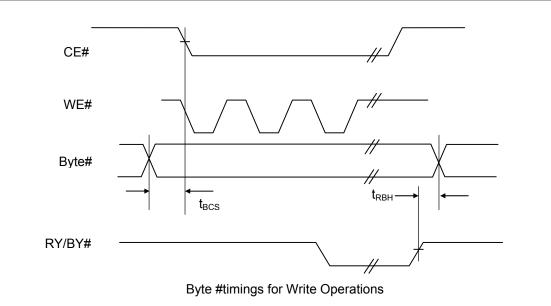
#### Table 19. Word / Byte Configuration (BYTE#)

Std		Test	Speed	1.1
Parameter	Description	Setup	-70	Unit
t <sub>BCS</sub>	Byte# to CE# switching setup time	Min	0	ns
t <sub>CBH</sub>	CE# to Byte# switching hold time	Min	0	ns
t <sub>RBH</sub>	RY/BY# to Byte# switching hold time	Min	0	ns

#### Figure 15. AC Waveforms for BYTE#



Byte# timings for Read Operations



**Note:** Switching BYTE# pin not allowed during embedded operations

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#### Table 20. Write (Erase/Program) Operations

Parameter Symbols		C	Description		Speed	Unit
JEDEC	Standard				-70	
t <sub>AVAV</sub>	t <sub>wc</sub>	Write Cycle Tim	e	Min	70	ns
t <sub>AVWL</sub>	t <sub>AS</sub>	Address Setup	Time	Min	0	ns
t <sub>WLAX</sub>	t <sub>AH</sub>	Address Hold Ti	me	Min	45	ns
t <sub>DVWH</sub>	t <sub>DS</sub>	Data Setup Tim	e	Min	30	ns
t <sub>WHDX</sub>	t <sub>DH</sub>	Data Hold Time		Min	0	ns
			Read	MIn	0	ns
	t <sub>OEH</sub>	Output Enable Hold Time DATA# Polling		Min	10	ns
t <sub>GHWL</sub>	t <sub>GHWL</sub>	Read Recovery Write (OE# High		Min	0	ns
$t_{\text{ELWL}}$	t <sub>cs</sub>	CE# SetupTime		Min	0	ns
t <sub>WHEH</sub>	t <sub>сн</sub>	CE# Hold Time		Min	0	ns
t <sub>WLWH</sub>	t <sub>WP</sub>	Write Pulse Wid	th	Min	35	ns
t <sub>WHDL</sub>	t <sub>WPH</sub>	Write Pulse Wid	th High	Min	20	ns
		Write Buffer Pro (Note 2, 3)	gram Operation	Тур	100	μs
t <sub>WHWH1</sub>	t <sub>WHWH1</sub>	Programming O		Тур	8	μs
		(Word AND Byte	e Mode)	Max	200	μs
				Тур	0.1	S
t <sub>WHWH2</sub>	t <sub>WHWH2</sub>	Sector Erase Op	peration	Max	2	s
		Chip Erase Operation		Тур	16	s
	t <sub>∨HH</sub>	$V_{HH}$ Rise and Fa	all Time	Min	250	ns
	t <sub>vcs</sub>	Vcc Setup Time		Min	50	μs
	t <sub>BUSY</sub>	WE# High to RY	//BY# Low	Max	70	ns
	t <sub>RB</sub>	Recovery Time	from RY/BY#	Min	0	ns

Notes: 1. Not 100% tested.

2. See table.22 Erase and Programming Performance for more information.

3. For 1~16 words bytes programmed.

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#### Table 21. Write (Erase/Program) Operations

#### Alternate CE# Controlled Writes

Parameter Symbols		Description		Speed	Unit	
JEDEC	Standard			-70		
t <sub>AVAV</sub>	t <sub>wc</sub>	Write Cycle Time	Min	70	ns	
t <sub>AVEL</sub>	t <sub>AS</sub>	Address Setup Time	Min	0	ns	
t <sub>ELAX</sub>	t <sub>AH</sub>	Address Hold Time	Min	45	ns	
t <sub>DVEH</sub>	t <sub>DS</sub>	Data Setup Time	Min	30	ns	
t <sub>EHDX</sub>	t <sub>DH</sub>	Data Hold Time Min		0	ns	
t <sub>GHEL</sub>	t <sub>GHEL</sub>	Read Recovery Time before Write (OE# High to CE# Low)	Min	0	ns	
t <sub>WLEL</sub>	t <sub>ws</sub>	WE# SetupTime	Min	0	ns	
t <sub>EHWH</sub>	t <sub>WH</sub>	WE# Hold Time	Min	0	ns	
t <sub>ELEH</sub>	t <sub>CP</sub>	Write Pulse Width	Min	35	ns	
t <sub>EHEL</sub>	t <sub>CPH</sub>	Write Pulse Width High	Min	20	ns	
		Write Buffer Program Operation (Note 2, 3)	Тур	100	μs	
t <sub>WHWH1</sub>	t <sub>wHwH1</sub>	Programming Operation	Тур	8	μs	
		(Byte AND word mode)	Max	200	μs	
+	+		Тур	0.1	S	
t <sub>WHWH2</sub>	t <sub>whwh2</sub>	Sector Erase Operation	Max	2	S	

Notes: 1. Not 100% tested.

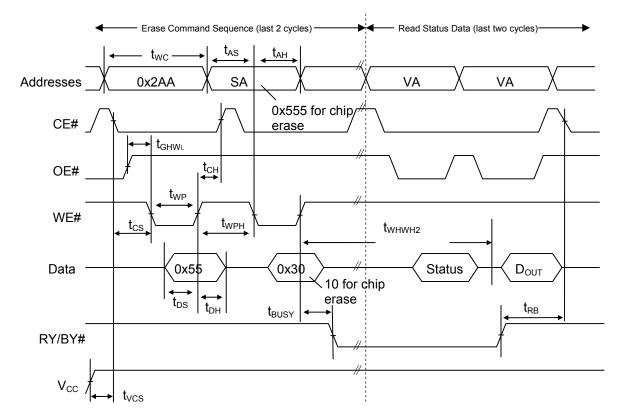
2. See table.22 Erase and Programming Performance for more information.

3. For 1~16 words bytes programmed.

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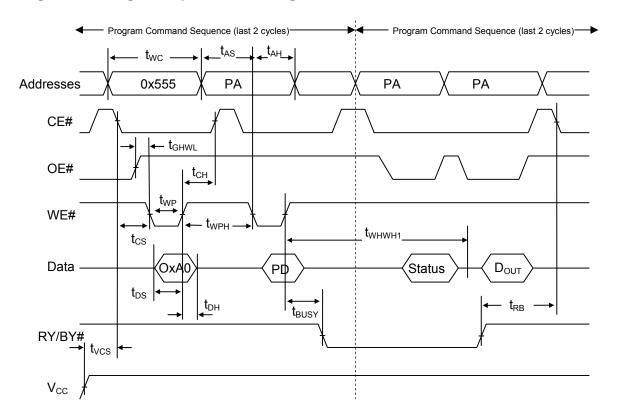
#### Figure 16. AC Waveforms for Chip/Sector Erase Operations Timings

Notes:

- 1. SA=Sector Address (for sector erase), VA=Valid Address for reading status, D<sub>out</sub>=true data at read address.
- 2. V<sub>cc</sub> shown only to illustrate t<sub>vcs</sub> measurement references. It cannot occur as shown during a valid command sequence.

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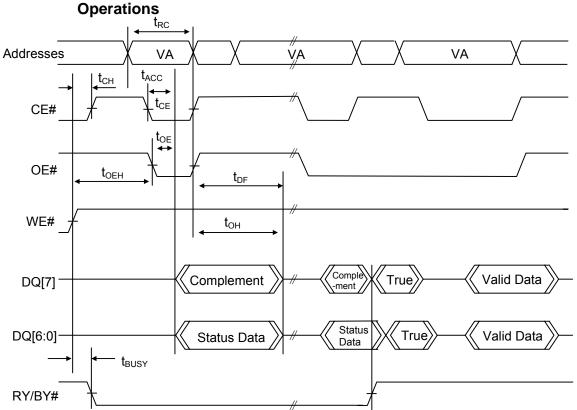


#### Figure 17. Program Operation Timings

Notes:

- 1. PA=Program Address, PD=Program Data,  $D_{OUT}$  is the true data at the program address.
- 2. V<sub>CC</sub> shown in order to illustrate t<sub>VCS</sub> measurement references. It cannot occur as shown during a valid command sequence.

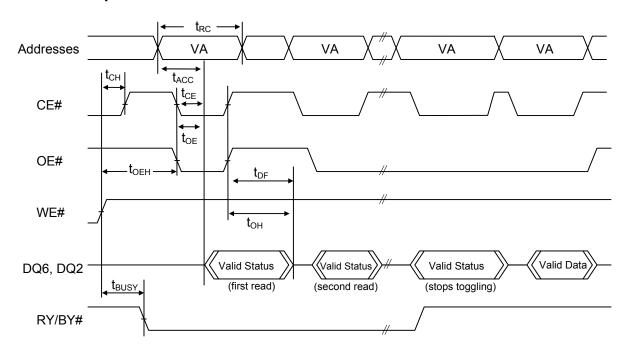




## Figure 18. AC Waveforms for /DATA Polling During Embedded Algorithm

Notes:1. VA=Valid Address for reading Data# Polling status data2. This diagram shows the first status cycle after the command sequence, the last status read cycle and the array data read cycle.

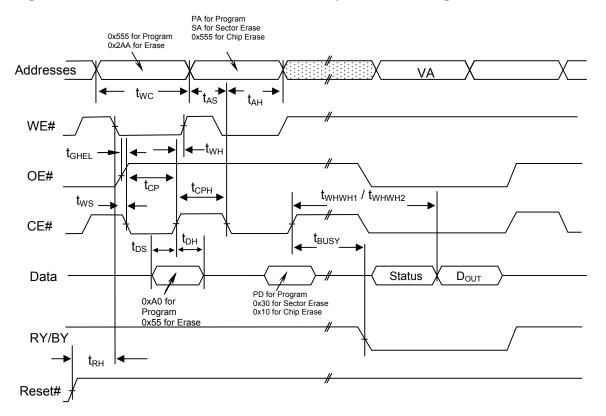
#### Figure 19. AC Waveforms for Toggle Bit During Embedded Algorithm Operations



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#### Figure 20. Alternate CE# Controlled Write Operation Timings

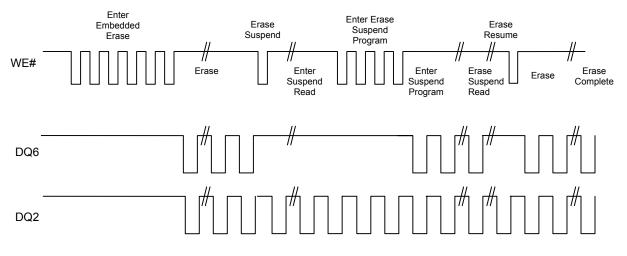
#### Notes:

PA = address of the memory location to be programmed. PD = data to be programmed at byte address. VA = Valid Address for reading program or erase status

D<sub>out</sub> = array data read at VA

Shown above are the last two cycles of the program or erase command sequence and the last status read cycle Reset# shown to illustrate  $t_{RH}$  measurement references. It cannot occur as shown during a valid command sequence.

#### Figure 21. DQ2 vs. DQ6



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Parameter	Parameter		Limits		Comments
i arameter		Тур	Max	Unit	Comments
Sector Erase Ti	me	0.1	2	sec	Excludes 00h programming prior
Chip Erase Time		16	60	sec	to erasure
Byte Programming Time		8	200	μs	
Word Programming	Word Programming Time		200	μs	
Chip Programming	Byte	67.2	201.6		Excludes system level overhead
Time	Word	33.6	100.8	sec	
Total Write Buffer	time	100			
ACC Total Write Buffer time		60		μs	
Erase/Program Endurance		100K		cycles	Minimum 100K cycles

#### TABLE 22. ERASE AND PROGRAMMING PERFORMANCE

Notes:

1. Typical program and erase times assume the following conditions: room temperature, 3V and checkboard pattern programmed.

2. Maximum program and erase times assume the following conditions: worst case Vcc, 90°C and 100,000 cycles.

#### Table 23. 56-PIN TSOP PIN CAPACITANCE @ 25°C, 1.0MHz

Parameter Symbol	Parameter Description	Test Setup	Тур	Max	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>IN</sub> = 0	6	7.5	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>OUT</sub> = 0	8.5	12	pF
C <sub>IN2</sub>	Control Pin Capacitance	V <sub>IN</sub> = 0	7.5	9	pF

**Note:** Test conditions are Temperature = 25°C and f = 1.0 MHz.

#### Table 24. DATA RETENTION

Parameter Description	Test Conditions	Min	Unit
	150°C	10	Years
Data Retention Time	125°C	20	Years

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#### **ABSOLUTE MAXIMUM RATINGS**

Par	ameter	Value	Unit
Storage	Temperature	-65 to +150	°C
Plastic	Packages	-65 to +125	°C
	Temperature Power Applied	-55 to +125	°C
Output Short Circuit Current <sup>1</sup>		200	mA
	OE#, RESET# and WP#/ACC <sup>2</sup>	-0.5 to + 9.5	V
Voltage with Respect to Ground	All other pins <sup>3</sup>	-0.5 to Vcc+0.5	V
	Vcc	-0.5 to + 4.0	V

Notes:

1. No more than one output shorted at a time. Duration of the short circuit should not be greater than one second.

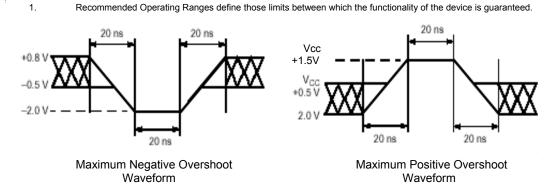
 Minimum DC input voltage on OE#, RESET# and WP#/ACC pins is -0.5V. During voltage transitions, OE#, RESET# and WP#/ACC pins may undershoot V<sub>ss</sub> to -1.0V for periods of up to 50ns and to -2.0V for periods of up to 20ns. See figure below. Maximum DC input voltage on OE#, and RESET# is 8.5V which may overshoot to 9.5V for periods up to 20ns.

3. Minimum DC voltage on input or I/O pins is -0.5 V. During voltage transitions, inputs may undershoot V<sub>ss</sub> to -1.0V for periods of up to 50ns and to -2.0 V for periods of up to 20ns. See figure below. Maximum DC voltage on output and I/O pins is V<sub>cc</sub> + 0.5 V. During voltage transitions, outputs may overshoot to V<sub>cc</sub> + 1.5 V for periods up to 20ns. See figure below.

Stresses above the values so mentioned above may cause permanent damage to the device. These values are for a stress rating only and do not imply that the device should be operated at conditions up to or above these values. Exposure of the device to the maximum rating values for extended periods of time may adversely affect the device reliability.

#### **RECOMMENDED OPERATING RANGES**<sup>1</sup>

Parameter	Value	Unit
Ambient Operating Temperature Industrial Devices	-40 to 85	°C
Operating Supply Voltage Vcc	Full Voltage Range: 2.7 to 3.6V	V

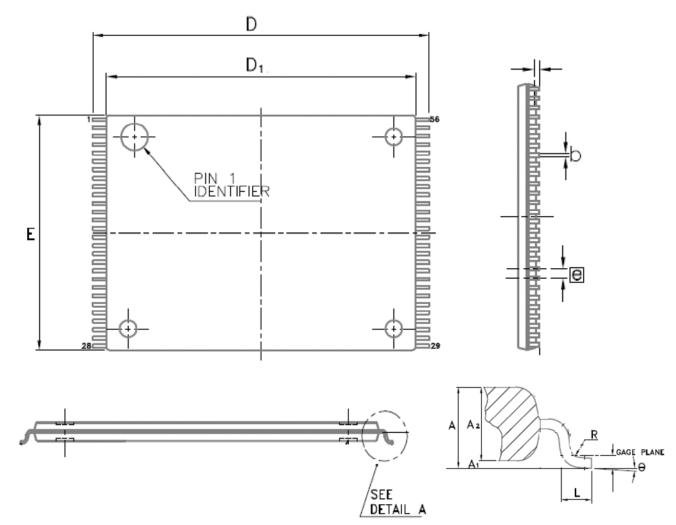


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DETAIL "A"

SYMBOL	DI	DIMENSION IN MM							
STMBOL	MIN.	NOR	MAX						
A			1.20						
A1	0.05		0.15						
A2	0.95	1.00	1.05						
D		20.00							
D1		18.40							
E		14.00							
е		0.50							
b	0.17	0.22	0.27						
L	0.5	0.60	0.70						
R	0.08	0.15	0.20						
θ	0 <sup>0</sup>	3 <sup>0</sup>	5 <sup>0</sup>						

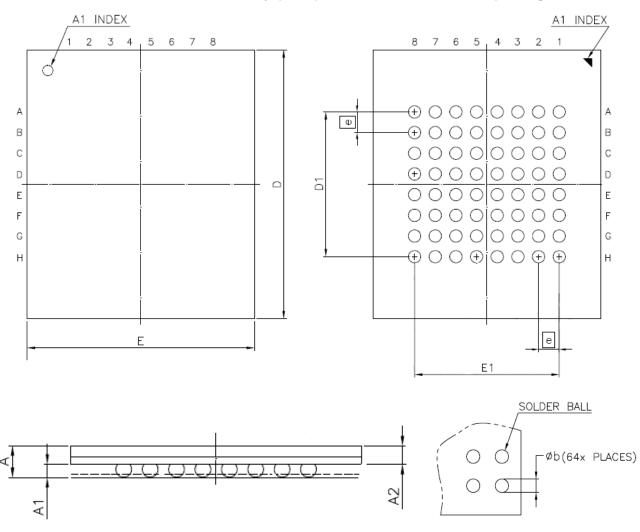
Note : 1. Coplanarity: 0.1 mm

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#### FIGURE 23. 64-ball Ball Grid Array (BGA), 11 X13 mm, Pitch 1mm package outline



SYMBOL	DI	DIMENSION IN MM								
STIVIDUL	MIN.	NOR	MAX							
Α			1.40							
A1	0.40	0.50	0.60							
A2	0.60	0.66	0.76							
D	12.90	13.00	13.10							
Е	10.90	11.00	11.10							
D1		7.00								
E1		7.00								
е		1.00								
b	0.50	0.60	0.70							

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### Purpose

Eon Silicon Solution Inc. (hereinafter called "Eon") is going to provide its products' top marking on ICs with < cFeon > from January 1st, 2009, and without any change of the part number and the compositions of the ICs. Eon is still keeping the promise of quality for all the products with the same as that of Eon delivered before. Please be advised with the change and appreciate your kindly cooperation and fully support Eon's product family.

### Eon products' Top Marking



cFeon Top Marking Example:

## cFeon

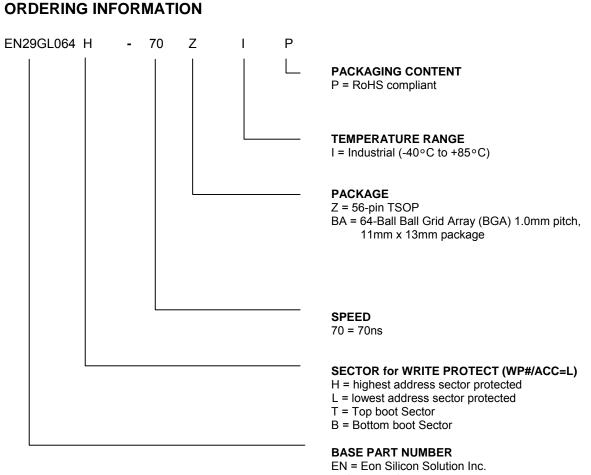
Part Number: XXXX-XXX Lot Number: XXXXX Date Code: XXXXX

### **For More Information**

Please contact your local sales office for additional information about Eon memory solutions.

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EN = Eon Silicon Solution Inc. 29GL = FLASH, 3V Page Mode Flash Memory 064 = 64 Megabit (8M x 8 / 4M x 16)

#### The valid combinations of EN29GL064.

Base Part Number	Sector for Write Protect (WP#/ACC=L)	Speed	Package	Temperature	Packaging Content
EN29GL064	Н	70	Z, BA	I	Р
	L	70	Z, BA	I	Р

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#### **ERRATA SHEET**

#### 1. INTRODUCTION

This errata sheet describes the functional deviation known at the release date of this document.

#### 2. Problem

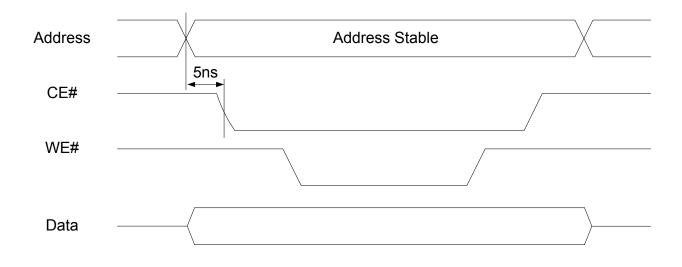
Write Buffer Program timing problem In general, the address setup time to CE# is 0ns. Due to timing problem, it may program to wrong address by Write Buffer Program function if address setup time is 0ns~1.5ns.

#### 3. Work-around

For Write Buffer Program function, we recommend minimum 5ns address to CE# setup time (address valid 5ns before CE# goes low).

In the case where CE# is kept low throughout the program buffer to flash command entry, A[max:12] should not be changes between Data=25h, Data=WC cycles to last Data= PD cycles and Data=29h cycle.

	s		Bus Cycles										
Command Sequence		1. <sup>st</sup> . (	Cycle	2 <sup>nd</sup> .	Cycle	3. <sup>rd</sup> . C	Cycle	4. <sup>th</sup> .	Cycle	5. <sup>th</sup> . C	Cycle	6 <sup>,th</sup> , 0	Cycle
		Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data	Addr	Data
Write to Buffer	6	555	AA	2AA	55	SA	25	SA	WC	PA	PD	WBL	PD
Program Buffer to Flash	1	SA	29										



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#### **Revisions List**

Revision No	Description	Date
A	Preliminary	2009/03/20
В	<ol> <li>Add internal pull-up description for WP# pin in Table1 in Page 4</li> <li>Add WP#/ACC, VIO pin in Figure3 in Page 4</li> <li>Modify tOE from 30ns to 25ns in Table 17 in page 40 and Page 5</li> <li>Add Secured Silicon Sector Entry/Exit command in Table13</li> <li>Modify typo from Sector Erase Suspend to Erase/Program Suspend, from Sector Erase Resume to Erase/Program resume in Table13</li> <li>Del table 22 and Figure 20 Temporary Sector Unprotect Timing table and Diagram and Figure 21.Sector Protect/Unprotect Timing Diagram</li> <li>Add ACC and total write buffer time spec in Table 22.</li> <li>Modify DC Characteristics in table 15 VHH from 10.5~11.5V to 8.5~9.5V</li> <li>ICC1 5MHz 20→15mA typ, 10MHz 30→25mA typ ICC4, ICC5 and ICC6 1→1.5uA typ, 5→10uA max Add IIO2 and IACCspec</li> <li>Del apply VID on address pin A9 to access autoselect codes function. (Remove TABLE 5 and modify description Autoselect section for using High voltage to get Autoselect Codes )</li> <li>Modify A9 spec from 9.5V to Vcc+0.5V in ABSOLUTE MAXIMUM RATINGS</li> </ol>	2009/05/12
С	<ol> <li>Modify naming for DQ0 OTP Lock Bit to Secured Silicon Sector Protection Bit in Page 33</li> <li>Modify Table.8 Secured Silicon Sector Address Range 000000h- 000007h from Determined by customer to Reserve for Factory</li> <li>Add note "The address 0h~7h in Secured Silicon Sector is reserved for Factory" in Page 39</li> <li>Update FIGURE 24. 64 ball Fortified Ball Grid Array (FBGA), 11 X13 mm, Pitch 1mm package outline in page 61</li> <li>Modify from Sector 0 to all sectors in note 1 of Table 6 and note 2, 3 and note 9 of PPB section in page 33</li> <li>Add "User only can use DQ6 and RY/BY# pin to detect programming status" in note 10 in page 33</li> </ol>	2009/7/14
D	<ol> <li>Add the 48-Ball (TFBGA) package information in page 1, 3, 61 and 64.</li> <li>Correct the Persistent Protection Bits status in page 31, 32 and 33.</li> <li>(1) Top boot: Sector 0~123 are 1 PPB per 4 sectors, Sector 124~134 have PPB for each boot sector.</li> <li>(2) Bottom boot: Sector 0~10 have PPB for each boot sector, Sector 11~134 are 1 PPB per 4 sectors</li> <li>3. Change the package code of 64-ball BGA in page 64.</li> </ol>	2009/07/22
E	Add the valid combinations of EN29GL064 on page 64	2009/09/07
F	Add a note "when sector SA0 is suspended, if system enters Secured Sector mode," on page 38.	2009/11/02
G	Add Write Buffer byte mode command and note that maximum value is 31 for word and byte mode in page 43	2010/03/15
Н	Correct the typo for The valid combinations of EN29GL064 table on page 64.	
I	<ol> <li>Remove 48-pin TSOP package type information on page 1, 2, 59 and 64.</li> <li>Remove 48-ball TFBGA package type information on page 1, 3, 61 and 64.</li> </ol>	2010/04/28
J	<ul> <li>1. Update Table 15. DC Characteristics on page 44.</li> <li>(1) Icc3 from 30mA to 40mA. (max.)</li> <li>(2) Icc4, Icc5, Icc6 from 1.5/10uA to 2.0/20uA (typ./max.)</li> <li>2. Update Chip Erase time from 140s to 60s (max.) on page 57.</li> </ul>	2010/05/11
К	1. Add ERRATA SHEET on page 63	2010/06/09
L	Remove VIO function.	2011/01/28
M	Revive VIO function.	2011/04/13

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N	<ol> <li>Remove VIO function.</li> <li>Add Table 6 "Note 3. If user needs the product of DQ3 = 0, please choose the EN29GA064AT/B.For the detail information of the EN29GA064AT/B, please contact with Eon directly" on page 32.</li> <li>Add Table 13 "Note: The data is 00h for an unprotected sector and 01h for a protected sector. This is same as PPB Status Read except that the protect and unprotect statuses are inverted here" on page42.</li> <li>Add Table 14 "Note: Protected State = "00h" Unprotected State = "01h"</li> </ol>
	<ol> <li>Add Table 14 "Note: Protected State = "00h," Unprotected State = "01h" on page43.</li> </ol>

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